# Instruction Manual FT-225RD FT-225R

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# YAESU MUSEN CO, LTD

TOKYO JAPAN

# ALL-MODE VHF MEMORY TRANSCEIVER FT-225RD FT-225R



The FT-225RD two meter transceiver is a precision-built communications module bringing state-of-the-art features together in a compact, rugged package. Capable of operation over the entire 144-148 MHz range, the FT-225RD provides the flexibility of SSB, CW, AM, and FM operation, and Yaesu's exciting memory feature, which allows storage and recall of any frequency within the 1 MHz band being used, is available as an option. Advanced PLL (Phase Locked Loop) circuitry offers unsurpassed stability and a clean, spurious-free output signal. All circuits are fully solid state, and computer type plug-in modules are used for increased reliability and ease of maintenance.

The FT-225RD provides output power in excess of 25 watts on FM, SSB, and CW, and 8 watts on AM. Deluxe features which are built into every FT-225RD are digital plus analog readout, VOX, semibreak-in CW with sidetone, noise blanker, discriminator center meter, and offset tuning (clarifier) for both receive and transceive frequencies. For tone burst repeater accessing, a programmable tone burst generator is included. The FT-225R, with analog display only, contains a crystal calibrator for precise frequency determination. The VFO coverage of the two-meter band is in 1 MHz segments, to avoid frequent changes of the bandswitch when crossing the 500 kHz point. In addition to VFO or optional memory operation, 44 crystal-controlled channels (11 channels x 4 bands) are possible. Repeater shift, which is normally set to 600 kHz, may be set to an alternative split of up to 1 MHz by the addition of an optional crystal or by use of the memory system.

The transceiver is entirely self-contained, requiring only an antenna and a power source for operation. The FT-225RD is normally supplied with 117 VAC and 13.6 VDC capability, but the power transformer may be rewired for operation from 100/ 110/117/200/220/234 VAC power. Two power cords are supplied with the transceiver. Selection of AC or DC operation is made by insertion of the proper line cord into the rear panel receptacle.

The transceiver weighs approximately 9 kg, and is 280 mm wide, 125 mm high, and 315 mm deep. Construction using heavy-gauge steel provides an extremely rugged package which is virtually immune to the effects of vibration and shock which are encountered in mobile service.

# SPECIFICATIONS

## GENERAL

### Frequency Range:

144 — 145 MHz 145 — 146 MHz 146 — 147 MHz 147 — 148 MHz

Frequency Readout: Digital readout to 0.1 kHz, analog display resolution better than 1 kHz.

Modes of Operation: LSB, USB, CW, AM, FM.

## **Frequency Stability:**

Within 100 Hz during any 30 minute period after warmup. Not more than 20 Hz with 10 % line voltage variation.

#### Intermediate Frequencies:

First IF = 10.7 MHz Second IF = 455 kHz

Antenna Impedance: 50 ohms unbalanced.

## **Repeater Split:**

600 kHz installed, any split up to 1 MHz possible with optional crystal.

## **Power Requirements:**

AC 100/110/117/200/220/234 Volts, 50/60 Hz

DC 11.5-16.0 Volts, negative ground

## **Power Consumption:**

AC Receive 30 VA Transmit 160 VA at full output power DC Receive 1.2 A Transmit 6.5 A

#### Size:

280 (W) x 125 (H) x 315 (D) mm

#### Weight:

Approx. 9.0 kg

## RECEIVER

Sensitivity:

SSB/CW 0.3 μV for 10 dB S/N FM 0.35 μV for 20 dB QS AM 1.0 μV for 10 dB S/N (400 Hz 30% modulation)

#### Selectivity:

SSB/CW/AM 2.3 kHz at 6 dB down 4.1 kHz at 60 dB down FM 12 kHz at 6 dB down 28 kHz at 60 dB down

Image Response: Better than -60 dB

Spurious Response: Better than  $1 \mu V$  at antenna input

Audio Output Impedance: 4 ohms nominal

Audio Output: 2 watts @ 10% THD

#### TRANSMITTER

Audio Response:  $350 \sim 2600 \text{ Hz} \pm 3 \text{ dB}$ 

Carrier Suppression: Better than - 40 dB

Unwanted Sideband Suppression: Better than - 40 dB

Spurious Radiation: Better than - 60 dB

FM Deviation: Factory set at ± 5 kHz, maximum ± 12 kHz

Power Output: SSB 24 watts PEP FM/CW 25 watts DC AM 8 watts DC

# SEMICONDUCTOR COMPLEMENT

Integrated Circuits (	IC):	Transistors:		Silicon Diodes:	
μPC14305	1	2SA496	1	181555	65
μPC14308S	2	2SA564A	1	1S1941	1
μPC78L05	1	2SA695	1	10D1	14
μPC1037H	1	2SB529	1	MC301	5
TA7045M	1	2SC372Y	34	U05B	1
<b>TA7061AP</b>	2	2SC373	9		
μA703HC	1	2SC496	7	Varactor Diodes:	
SN76514	1	2SC710	2	1\$2208	2
SN75450B	1	2SC711	1	1\$2209	14
SN75453	3	2SC730	1	1SV50	1
MC14011B	4	2SC735Y	2	FC63	1
MC4044P	1	2SC784R	10		
(µPC1008C)		2ŠC1000BL	2	Zener Diodes:	
MSM561	1	2SC1000GR	4	1N4732	1
MSM5564	1 .	2SC2053	2	WZ090	1
MSM5576	1	2SD313D	2	WZ110	1
F4011	1	2SD359	1		
TC5032	1	2N5591	1	Light Emitting Dio	des (LED):
		<b>MRF212</b>	1	GD4-203SRD	11
Field Effect Transist	ors (FET):	MJ802	1	021200510	R R).
2SK19BL	1	Germanium Diodes	5:	LED Display:	
2SK19GR	11	1S188FM	9	5082-7740	7
2SK19Y	1	1S1007(GB)	10	5002 / 10	
3SK40M	2				
3SK51	2				

Specifications subject to change without notice.

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This transceiver has been specifically designed for ease of operation and versatility. All internal controls have been carefully preset at the factory. The operator may, however, be unfamiliar with the operation of some of the controls, and improper adjustment thereof may result in poor transceiver performance. The various front panel controls and switches are described in the following section, and the operator should be familiar with the function of every control before attempting transceiver operation.



## (1) MODE switch

This switch chooses the mode of operation: LSB, USB, CW, AM, or FM.

#### (2) CLARIFIER

The clarifier control allows a means of offsetting the transceive or receive frequency  $\pm 4$  kHz from the frequency established by the main VFO dial.

## (3) MAIN TUNING DIAL

The tuning control is a dual rate, double-shaft mechanism which provides for both fast and slow tuning rates. The main dial skirt is calibrated in 1 kHz increments, and the analog dial window is calibrated in 100 kHz increments. Determination of the 1 MHz band segment is made by the BAND switch.

#### (4) SELECT switch

This switch selects frequency control between the VFO/FIX mode and memory (optional) control of the transmit, receive, or transceive frequency.

#### (5) BAND switch

The BAND switch selects one of the four 1 MHz segments of the two-meter band.

#### (6) MEMORY

When the optional memory unit is installed, a new frequency may be stored in memory by pressing the MEMORY switch.

## (7) CHANNEL

This switch selects between VFO control or one of the 11 crystal controlled positions available per band.

## (8) DIM

This switch, when pressed, dims the front panel lamps and the digital display for reduced power consumption or nighttime mobile operation.

## (9) BURST

This switch activates the tone burst generator.

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## (10) AF GAIN

The AF GAIN control adjusts the audio output level to the speaker and headphones. Clockwise rotation increases the audio output level.

## (11) SQUELCH

This control adjusts the FM receiver squelch threshold level.

### (12) NB

This switch, when pressed, activates the noise blanker for elimination of pulse-type noise. The noise blanker is not operative in the FM mode, because impulse noise is amplitude modulation and the FM receiver does not respond to such noise.

## (13) TUNE

The TUNE control peaks all transceiver signal circuits for the frequency being used.

## (14) RF GAIN

The RF GAIN control varies the gain of the receiver IF and RF amplifiers. Maximum sensitivity is obtained when the control is set to the fully clockwise position.

## (15) ATT

When pushed, the ATT (RF attenuator) places approximately 20 dB of attenuation in the incoming receive signal path, thus preventing overload of the receiver front end.

#### (16) SSB MIC GAIN

This control varies the output from the microphone amplifier stages for SSB and AM operation. The control has sufficient range to permit the use of any 500–600 ohm dynamic microphone.

## (17) PWR CONTROL

This control allows continuously variable power output adjustment, when it is desirable to reduce the level of the transmitted signal, as, for example, when a transverter is used that requires very little driving power.

#### (18) DIAL

Frequency readout is by means of the digital and the analog displays. The digital display reads out all digits of the operating frequency, with resolution to 100 Hz. The analog sub-dial is calibrated every 100 kHz, and the BAND switch and main dial skirt are used to establish the precise operating frequency.

## (19) **METER**

The meter reads signal strength or FM discriminator center current on receive, and relative power output on transmit.

## (20) VOX GAIN

The VOX GAIN control selects between PTT and MOX (manual transmit) operation, and adjusts the level of the VOX amplifier stage.

## (21) FUNCTION switches

## RPT

This switch is used for repeater operation. For operation in the U.S., the transmitter frequency is shifted 600 kHz lower in the 144, 145, and 146 MHz bands, and in the 147 MHz band, the transmit frequency is shifted 600 kHz higher. The offset may be reversed by placing this switch in the REV position.

#### AUX/600 kHz

This switch selects the normal 600 kHz repeater offset or an auxiliary split established through use of an optional crystal.

## DISC

This switch selects between meter indication of discriminator center current or signal strength on receive.

#### AGC

This switch selects between slow and fast AGC action.

#### **CLARIFIER** switch

The CLARIFIER switch selects between transceive frequency or receive frequency offset using the clarifier control. In the center (horizontal) position the clarifier is switched off.

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## (22) POWER

This is the main ON/OFF switch for both AC and DC operation.

## (23) PHONES

This is a miniature phone jack for use of headphones or a speaker. The internal speaker is disabled when a plug is inserted into this jack.

## (24) MIC

This is a four-conductor jack for microphone and PTT connections.









Key Plug



**Headphone** Plug



**Microphone** Connector





**Phono Plug** 



Tone In Plug

# REAR PANEL CONNECTIONS



## (1) ANT

UHF female coaxial connector for antenna input.

#### (2) GND

Ground connection.

## (3) ALC

ALC (automatic level control) input.

## (4) RL (make, break, common)

Relay contacts for control of station equipment.

## (5) SP

External speaker audio output.

#### (6) KEY

Key jack for CW operation.

## (7) TONE-IN

Tone pad input jack.

## (8) FUSE

Fuse holder. For AC operation, a 3 amp fuse is used on 117 volts, and a 2 amp fuse is used for 220 volt operation. For DC operation, a 10 amp fuse is located in the DC power cord. When replacing fuses, be certain to replace the blown fuse with one of the proper rating. WARRANTY DOES NOT COVER DAMAGE CAUSED BY IMPROPER FUSE REPLACEMENT.

## (9) POWER receptacle

Both AC and DC cables are connected to this receptacle. They are both supplied with the transceiver.

## INSTALLATION

### GENERAL

The FT-225RD has been designed primarily for base station service, requiring only an antenna and power source. However, the transceiver provides for efficient mobile operation. The transceiver has been factory pre-tuned and requires no adjustment for operation into a 50 ohm resistive load.

The antenna and its location are of critical importance in both fixed and mobile operation. In most cases, communications effectiveness is directly related to antenna height. The antenna should be as high and in the clear as possible, and a minimum separation of 5 feet should be maintained between VHF and other antennas. In mobile operation, it is desirable to locate the antenna as far away from the engine as paracticable so as to avoid noise pickup from the ignition system. The most popular mobile antennas are the 1/4 wavelength whip, and the 5/8 wavelength whip which provides approximately 3.5 dB gain over the 1/4 wavelength whip. The Yaesu RSL-145 mobile antenna is available through your dealer.

To minimize loss in the antenna system do not economize on coaxial cable, and use the shortest length of cable that is practical, avoiding sharp angles or kinks. Use type RG8A/U if the transmission line length exceeds 25 feet, while RG-58A/ U may be used for shorter runs. Type RG-17A/U, air-dielectric "heliax", or aluminum-jacketed foam-dielectric coax should be used for very long runs.

## **BASE STATION INSTALLATION**

The transceiver is designed for use in many areas of the world where the supply voltage may differ from the operator's local supply voltage. Therefore, before connecting the AC cord to the power outlet, be absolutely certain that the voltage marked on the rear of the transceiver agrees with the local AC supply voltage. If not, please refer to the transformer primary winding chart for the proper connections.

#### CAUTION

PERMANENT DAMAGE WILL RESULT IF IM-PROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER; OUR WARRANTY DOES NOT COVER THE DAMAGE CAUSED BY SUCH AN IMPROPER SUPPLY VOLTAGE.

Be sure that a proper fuse is used for the local supply voltage: 3 amps for 117 volts and 2 amps for 220 volts. The transceiver should be connected to a good ground. The ground lead should be connected to the terminal marked GND on the rear panel.

It is recommended that excessively warm locations be avoided. The transceiver should be placed in a location that has adequate space to permit free air circulation through the cabinet openings.



POWER TRANSFORMER PRIMARY CONNECTIONS

#### MOBILE INSTALLATION

The transceiver will operate satisfactorily from any 12 volt negative ground battery source by connecting the DC power cord to the rear panel receptacle. In the car, a location should be selected that is clear of heater ducts to protect it from excessive heat. No special mounting precautions need to be observed if adequate ventilation is available. A minimum of two inches of air space is recommended to allow proper air flow around the transceiver. You may put it on the seat but be sure there is clearance between the cabinet bottom and the seat. Since the transceiver requires an average of 6.5 A on transmit, the fuse in the DC power cable should be rated for 10 amps.

When making connections to the car battery, be certain that the RED lead is connected to the positive (+) terminal and the BLACK lead is connected to the negative (-) terminal of the battery. Reversed connections could permanently damage the transceiver. The power cable should be as short as possible, and should be connected to the battery so as to take advantage of the filtering action of the battery.

Prior to operating the transceiver in a mobile installation, the voltage regulator setting should be checked. In many vehicles, the voltage regulation is very poor, and in some cases the regulator may be set for an excessively high charging voltage. As the battery and regulator age, the maximum voltage while charging can increase to a very high level. This is not only detrimental to the battery, but it may damage the transceiver. The transceiver is designed to operate from a source voltage of 11-16.5 volts. It is desirable to set the regulator so that the highest charging voltage does not exceed 14 volts, so as to give a margin of safety. The transceiver should be switched OFF when the vehicle is started so as to prevent voltage transients from damaging the transistors.

It is recommended that the microphone furnished with this transceiver be used: however, any quality microphone of 500-600 ohm impedance may be used. Refer to Fig. 2 for the microphone plug wiring connections. The microphone bracket may be put on the side of the cabinet, or at any other convenient place by drilling two 2.5 mm holes spaced 13 mm. A speaker is built into the transceiver. However, audio output is also available for use with an external speaker. Any speaker having an impedance of 4 ohms may be used. When an external speaker plug is inserted in the EXT SP jack on the rear panel, the internal speaker is disabled. The tuning procedure for this transceiver is not complicated. However, care should be exercised in operation to ensure peak performance. The following paragraphs describe the procedure for receiver and transmitted tuning.

## **INITIAL CHECK**

Before connecting the transceiver to a power source, carefully examine the unit for any visible damage. Be sure that all modules and crystals are firmly in place, and that controls and switches are operating normally. Be certain that the voltage specification marked on the rear panel matches the supply voltage.

## **FREQUENCY READOUT**

The digital display includes all digits of the operating frequency, with accuracy to 0.1 kHz.

The analog display consists of three components: the bandswitch, the analog dial window, and the main tuning dial skirt. For example, let us say it is desired to operate on 145.250 MHz. The bandswitch should be placed in the "145" position, the main dial should be rotated so that the dial window indicates half way between "200" and "300", and the dial skirt should indicate "50". By changing the position of the bandswitch, this positioning of the main tuning dial will also yield 144.250, 146.250, and 147.250 MHz.



## RECEIVER

After the transceiver is properly set up for operation, set the controls and switches as follows:

POWERDown to OFF positon
MODEDesired mode
BANDDesired band segment
RPT Lever position horizontal
to OFF position
AUX/600 kHzLever position horizontal
for 600 kHz shift
DISCLever position horizontal
to S-meter position
CLAR Lever position horizontal
to OFF position
Main tuning dial Desired operating fre-
quency
VOX GAIN PTT
AF GAINAdjust subsequently for
comfortable level
RF GAIN
SELECTVFO/FIX
CHANNELVFO
SQUELCH
NBOFF (not depressed)
ATTOFF (not depressed)
AGCSlow or fast, as desired

Connect the appropriate power cord to the proper power source, and connect an antenna to the antenna connector on the rear panel.

#### CAUTION

PERMANENT DAMAGE WILL RESULT IF IM-PROPER SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER. WARRANTY DOES NOT COVER THE DAMAGE CAUSED BY IMPROPER SUPPLY VOLTAGE.

Turn on the POWER switch. The dial and meter lamps and digital display LED's should light up; the transceiver is now ready to operate. Peak the TUNE control for maximum receiver background noise; this will also peak the transmitter circuits for maximum power output.

## (1) SSB and AM Modes

Using the main tuning control, tune in an SSB signal. Upper sideband (USB) is the more commonly used mode for 2 meter SSB operation; if, however, the incoming station, cannot be tuned in, he or she may be using lower sideband (LSB). The RF GAIN control is normally set to the fully clockwise position, but if the incoming signal is extremely strong, or if you are trying to copy a weak station adjacent to an extremely strong station, reducing the RF GAIN control setting may improve reception. When pulse-type noise such as ignition noise is encountered, press the NB (noise blanker) switch.

## (2) CW Mode

With the clarifier in the OFF position, tune in a CW signal. When the incoming signal is tuned to a beat note of 800 Hz, your transmit frequency will coincide with that of the other station. If another beat note is desired, or if the other station drifts, then use the clarifier control.

## (3) FM Mode

Using the main tuning control, tune in an FM signal for a maximum and steady S-meter reading and a clear, natural voice output from the speaker. For accurate tuning, set the meter switch to the DISC position, and carefully readjust the tuning control until the pointer is exactly vertical (zero on the discriminator scale).

If the S-meter wobbles, or if it is impossible to obtain clean audio, it is possible that the incoming signal is on another mode, such as SSB.

## FREQUENCY CALIBRATION

## (1) FT-225RD (Digital plus analog model)

The digital display is automatically calibrated, and no further adjustment is needed. The analog dial skirt should be rotated so that it coincides with the frequency shown on the digital display.

## (2) FT-225R (Analog model)

## A. SSB/CW Modes

Activate the MARK switch, rotate the main tuning dial to the nearest 100 kHz point, and tune in the marker signal for a zero beat (lowest pitch frequency). Rotate the dial skirt, so as to align the "0" calibration with the vertical calibration marking. The transceiver must be recalibrated when changing modes, as, for example, when changing from LSB to USB.

## B. AM Mode

Activate the MARK switch, and rotate the main tuning dial to the nearest 100 kHz point, and tune in the marker signal for a maximum S-meter reading. Rotate the dial skirt to align the "0" calibration with the vertical calibration marking.

## C. FM Mode

Place the meter switch in the DISC position. Activate the MARK switch, and rotate the main tuning dial to the nearest 100 kHz point. Tune in the marker signal for a vertical indication of the meter pointer ("0" on the discriminator center meter). Rotate the dial skirt for calibration at the "0" point, as in the previous sections.

NOTE: WHEN THE MARKER SWITCH IS ACTI-VATED, THE ANTENNA IS DIS-CONNECTED FOR EASIER CALI-BRATION.

## TRANSMITTER

Connect a 50 ohm dummy load or matched antenna to the coaxial fitting on the rear panel. If the TUNE control has been adjusted no further adjustment is needed for full transmitter output. The adjustment of the TUNE control for maximum output is very broad.

For adjustment of the power output level, the PWR CONTROL may be rotated as required. Some transverters require very little drive power for proper operation, and this control allows the operator to control the transmitter output level as needed.

## (1) SSB Mode

The SSB MIC GAIN control should be adjusted while speaking in a normal voice a long syllable such as the word "four". The SSB MIC GAIN control should only be advanced to the point where the output does not increase further. Excessive advancement of the gain control will result in splatter and distortion, thus reducing intelligibility. The microphone PTT switch may be used, or the VOX circuitry may be utilized (see part (5) of this section).

## (2) AM Mode

When the microphone PTT switch is depressed, the proper amount of carrier is automatically inserted. Adjust the SSB MIC GAIN control until the meter indicates a very slight movement with voice peaks while speaking into the microphone in a normal voice.

## (3) CW Mode

Plug a key into the KEY jack on the rear panel. In the key-down condition, the meter will indicate between 6 and 8 on the relative output scale. For semi-break-in operation, advance the VOX GAIN control until the sidetone oscillator activates the VOX relay when the key is closed. For PTT operation, rotate the VOX GAIN control to the PTT position. Keying is accomplished by closing the DC 8V line to ground. Key down current is approximately 8 mA. Use caution when utilizing an electronic keyer so as to avoid damage due to reversed polarity.

## (4) FM Mode

Push the PTT switch on the microphone while speaking normally into the microphone. The mic gain is automatically set in the FM mode. While transmitting, the relative output meter will read between 6 and 8. Release the microphone PTT switch for return to receive.

## (5) VOX (Voice Controlled) Operation

Adjust the VOX GAIN control on the front panel until your voice actuates the transmitter while you are speaking in a normal voice into the microphone. Set the antitrip control  $VR_{402}$ , which is located on the AF AMP UNIT, to the minimum point that prevents the speaker output from tripping the VOX circuit. Do not use more VOX GAIN nor ANTITRIP than necessary. Adjust the DELAY control  $VR_{401}$  for the desired release time. The RELAY control provides a coarse adjustment for the relay sensitivity, and this has been preset at the factory. The RELAY and DELAY controls are also located on the AF AMP UNIT.

## (6) PTT Operation

Push-to-talk operation is accomplished by rotating the VOX GAIN control to the PTT position (but not into the click-stop, which is the MOX position). The PTT circuit may then be activated either by the microphone PTT switch, or by a footswitch. If a footswitch is used, it may be connected through the rear panel TONE IN jack; the switch should be connected between pin 3 and ground.

## **REPEATER OPERATION**

The transmit frequency may be shifted 600 kHz for repeater operation. When the RPT switch is in the NOR (normal) position, the transmit frequency is shifted 600 kHz lower in the 144, 145, and 146 MHz bands, and 600 kHz higher in the 147 MHz band (US model). These relations are reversed when the RPT switch is placed in the REV position. That is, on the 144, 145, and 146 MHz bands, when the RPT switch is placed in the REV position, the receive frequency is shifted 600 Hz down; on 147 MHz, the receive frequency is shifted 600 kHz up. Extreme caution should be exercised so as not to transmit outside the amateur bands while using the RPT switch.

In some areas, repeater splits other than 600 kHz have been authorized. In this case, an optional crystal may be installed in the local unit to provide repeater splits of up to 1 MHz. The AUX/600 kHz switch must be placed in the AUX position for actuating the optional crystal.

Determination of the AUX crystal frequency is made as follows:

Band 144 (144.0-145.0 MHz)
$(125.1 + Shift frequency) \div 9$
$(125.1 - \text{Shift frequency}) \div 9$
Band 145 (145.0-146.0 MHz)
$(126.1 + Shift frequency) \div 9$
$(126.1 - \text{Shift frequency}) \div 9$
Band 146 (146.0–147.0 MHz)
$(127.1 + Shift frequency) \div 9$
$(127.1 - \text{Shift frequency}) \div 9$
Band 147 (147.0–148.0 MHz)
$(128.1 + Shift frequency) \div 9$
$(128.1 - \text{Shift frequency}) \div 9$

## Example 1

Calculate the crystal frequency for -800 kHz shift in the 146 MHz band segment (TX frequency 800 kHz lower):

 $(127.1 - 0.8) \div 9 = 14.033$  MHz

## **Example 2**

Calculate the crystal frequency for +800 kHz shift in the 147 MHz band segment (TX frequency 800 kHz higher):

 $(128.1 + 0.8) \div 9 = 14.3222$  MHz

When the optional memory unit is installed, the output frequency of the repeater may be stored by pressing the MEMORY button and placing the SELECT switch in the SIMPLEX position. By placing the RPT switch in the NOR or REV positions, the desired offset will occur. If the repeater input and output frequencies are within the same 1 MHz width of the BAND switch, the input frequency may be stored in memory, and then recalled for transmission only by placing the SELECT switch in the TX MR position. The VFO can then be tuned to the output frequency of the repeater. In this way, "oddball" splits can be accommodated.

Tone actuated repeaters can be accessed by means of the built-in tone burst generator, which is actuated by pressing the BURST switch on the front panel. With this button depressed, pushing the microphone PTT witch will cause insertion of the burst signal at the beginning of each transmission. The audio frequency of the tone burst signal may be programmed for any frequency between 671 and 2900 Hz, by use of a crystal and by positioning the selector plug on the tone burst unit. The US model normally is set up for 1800 Hz operation, and the European model for 1750 Hz operation. The charts will show the relation between the position of the selector plug, the crystal frequency, and the tone frequency. Moving the selector plug will change the tone frequency by a factor of two or four, as shown in the charts.

Tone Frequency	Multiplier	Plug Position	Crystal Frequency
(Hz) 671–1342	4096	A	<sup>(kHz)</sup> 2750-5500
1343 - 2685	2048	В	2750 - 5500
2686 - 2900	1024	С	2750-2970

Crystal frequency = Tone frequency  $\times$  Multiplier.



BAND	Simplex/Split	Local Frequency	Crystal Frequency	Multiplier
144	Simplex	★ 125.1 <sup>(MHz)</sup>	13.9000 <sup>(MHz)</sup>	
	+600kHz Shift	125.7	13.9666 ••	
	-600kHz Shift	★ 124.5	13.8333	
	Simplex	* 126.1	14.0111	
145	+600kHz Shift	126.7	14.0777 · ·	
	-600kHz Shift	★ 125.5	13.9444 • •	
	Simplex	* 127.1	14.1222 · ·	imes9
146	+600kHz Shift	127.7	14.1888	
	-600kHz Shift	* 126.5	14.0555	
147	Simplex	★ 128.1	14.2333 ••	
	+600kHz Shift	★ 128.7	14.3000	
	-600kHz Shift	127.5	14.1666	

Table 1 (★ US model)

## **CRYSTAL CONTROLLED OPERATION**

In addition to normal VFO operation, eleven crystals may be selected by the channel switch on the front panel for crystal controlled operation. Such operation is often useful for operation on favorite calling or repeater frequencies. Since the 2 meter band is divided into four segments in the FT-225RD, these eleven crystals could provide for operation on 44 different frequencies.

The crystal holders accept standard HC-25/U type crystals. All crystal frequencies must fall between 8,200 kHz and 9,200 kHz. A trimmer capacitor is connected in series with each crystal to permit fine tuning of the crystal frequency; Adjustment of this trimmer will move the crystal frequency approximately 1 kHz.

The correct crystal frequency for any desired operating frequency may be determined by using the following formula:

$$f_x = f_0 - f_1$$

where  $f_x = crystal$  frequency  $f_0 = operating$  frequency  $f_1 = a$  constant shown in Table 3

**Example**: Calculate the required crystal frequency for 144.25 MHz CW operation.

 $f_x = f_0 - f_1 = 144250 - 135799.3 = 8450.7 \text{ kHz}$ 

It can be seen from the chart that a crystal for 144.51 MHz FM can also be used for 145.51, 146.51, and 147.51 MHz FM by changing the position of the BAND switch.

## MEMORY OPERATION (With optional MEMORY UNIT installed)

The memory circuitry can be used to store any frequency within a 1 MHz band segment for recall and control of the receive, transmit, or transceive frequencies. A frequency is memorized by pressing the MEMORY button, and the frequency is recalled by positioning the SELECT switch as needed. In the SIMPLEX position, the transceive frequency is locked on the memorized frequency. In the TX MR position, the transmitter is locked on the memorized frequency, and the receiver is controlled by the main VFO (or FIX unit). In the RX MR position, the transmitter is locked on the memorized frequency, and the transmitter is controlled by the main VFO.

Caution should be observed during repeater operation: if the SELECT switch is in the TX MR position, for example, and the RPT switch is in the NOR position, the 600 kHz shift will be applied to the memorized frequency, which will be recalled during transmission periods. Unless the operator is careful, an unwanted repeater may be activated, causing interference to other users.

Optional batteries inserted in the MEMORY UNIT will allow the memorized frequency to be held, even though the FT-225RD is turned off.

For most repeater work, the memorized repeater frequency can be recalled by placing the SELECT switch in the SIMPLEX position, and placing the RPT in the NOR or REV position as needed. The main VFO may then be turned to another frequency, such as another repeater or calling frequency; return to the VFO frequency is made by placing the SELECT switch in the VFO/FIX position. Alternatively, the repeater input frequency may be memorized and recalled by placing the SELECT switch in the TX MR position; the VFO can then be turned to the repeater output frequency, and the RPT switch should be OFF.

BAND		f		
(MHz)	LSB(MHz)	$USB(M\!H_Z)$	AM · FM (MHz)	CW (MHz)
144~145	135.8015	135.7985	135.8000	135.7993
145~146	136.8015	136.7985	136.8000	136.7993
146~147	137.8015	137.7985	137.8000	137.7993
147~148	138.8015	138.7985	138.8000	138.7993

Т	ab	le	3



## CIRCUIT DESCRIPTION

#### GENERAL

The block diagram and circuit description below will provide you with a better understanding of the transceiver. Computer-type plug-in modules are utilized throughout this transceiver.

The FT-225RD uses a single conversion receiver with a 10.7 MHz IF for SSB, CW, and AM; a double conversion receiver with a 10.7 MHz first IF and a 455 kHz second IF is used for FM. A single conversion transmitter, utilizing a 10.7 MHz high frequency crystal filter for SSB generation, and varactor diode frequency modulation of a 10.7 MHz crystal oscillator, is incorporated.

Each printed board has its own parts numbers, beginning, usually with number  $-_{01}$ . For example, the IF amplifier transistor 2SC784R on PB-1778 is Q<sub>201</sub>.

#### RECEIVER

#### RX RF UNIT (PB-1746)

The 144 MHz input signal from the antenna is fed through the antenna relay  $RL_{701}$  to pin 5 of the RX RF unit. The signal is then amplified by RF amplifier  $Q_{102}$  (3SK51), a field effect transistor, and then fed to gate 1 of the first mixer  $Q_{103}$ (3SK40M), where the input signal is heterodyned with a 133.3 MHz to 137.3 MHz signal delivered from the PLL unit, thus producing an IF signal of 10.7 MHz at the drain of  $Q_{103}$ . The input and output circuits of the RF amplifier utilize a double tuned circuit, which is sharply tuned to the center of the band by varactor diodes  $D_{105} - D_{108}$  (1S2209), thus eliminating cross modulation and intermodulation effects.

The IF signal passes through crystal filters  $XF_{101}$ and  $XF_{102}$  (both 10M2A2), and the SSB, AM, and CW signal is then fed to the first IF amplifier Q<sub>105</sub> (2SC784R); the FM signal is fed to Q<sub>104</sub> (2SC784R). The amplified SSB, CW or AM signal is fed through a noise blanker gate diode D<sub>109</sub> (1S1007) to pin 14 of the printed board, while the amplified FM signal is fed to pin 9.

#### SSB IF UNIT (PB-1778)

The SSB, AM, and CW signal from pin 14 of the RX RF unit is fed through pin 3 of the SSB IF unit. The signal is then fed through a diode switch and a crystal filter XF<sub>201</sub> (XF10A) to the IF amplifier Q<sub>201</sub> (2SC784R). The signal is amplified by Q<sub>201</sub> and Q<sub>208</sub> (TA7045M), and then fed to the balanced demodulator Q<sub>209</sub> ( $\mu$ PC1037), where a carrier signal is applied through pin 32 from the carrier oscillator in the MIC AMP unit.

The audio output is fed through pin 33 and the MODE switch S3D to pin 25 of the printed board. The IF signal is further amplified by  $Q_{202}$  (2SK-19GR), and detected by the AM detector  $D_{204}$  (1S188FM) in the AM mode. The audio signal is then fed through pin 28 to the MODE switch S3D.



RX RF UNIT

A portion of the IF signal output from  $Q_{202}$  is rectified by  $D_{205}$  (1S1555) and  $D_{206}$  (1S1007) for AGC (automatic gain control) purposes. The AGC voltage is amplified by  $Q_{203}$  and  $Q_{204}$  (both 2SC373); this voltage controls the gain of IF amplifiers  $Q_{201}$  and  $Q_{208}$ . A portion of the AGC voltage is fed through pin 17 to the RX RF unit to control the gain of RF amplifier  $Q_{102}$ . The AGC voltage is amplified by the S-meter amplifier  $Q_{204}$ (2SC373) and fed to the S-meter through the DISC/S METER switch on the front panel.

The audio signal from the MODE switch is preamplified by  $Q_{205}$  and  $Q_{206}$  (both 2SC100BL) and fed through pin 29 to the AF AMP unit.

#### FM IF UNIT (PB-1463)

The FM IF signal from pin 17 of the printed board is fed through a ceramic filter  $CF_{303}$  (10.7 MF BR) to the second mixer  $Q_{305}$  (2SC372Y), where the 10.7 MHz signal is mixed with the 10.245 MHz signal generated by the second heterodyne oscillator  $Q_{309}$  (2SC372Y), thus producing a 455 kHz second IF signal. The 455 kHz IF signal is fed through a ceramic filter  $CF_{302}$  to the second IF amplifier  $Q_{306}$  and  $Q_{307}$  (both 2SC372Y) and also to the amplifier limiter  $Q_{308}$  (TA7061AP), which removes any amplitude modulation component of the signal. The output of  $Q_{308}$  is applied to the discriminator  $D_{303}$  and  $D_{304}$  (both 1S188FM). The discriminator produces an audio output in response



SSB IF UNIT



FM IF UNIT

to a corresponding frequency (or phase) shift in the 455 kHz IF signal. The discriminator output is then fed to the common audio amplifier stage in the SSB IF unit through the MODE switch.

For FM reception, when no carrier is present in the 455 kHz IF, the noise at the discriminator output is fed through the squelch threshold potentiometers VR<sub>6</sub> and VR<sub>1b</sub> to the noise amplifier Q<sub>310</sub> and Q<sub>311</sub> (2SC372Y), and is detected by D<sub>805</sub> and D<sub>806</sub> (1S188FM). The DC voltage is applied from pin 8 to the squelch controller Q<sub>401</sub> (2SC372Y) in the AF AMP unit.

The 10.7 MHz signal is also applied to the noise blanker amplifier  $Q_{301}$  (2SC372Y). The signal is amplified by  $Q_{301}$  and  $Q_{302}$  ( $\mu$ A703HC). The noise rectifier diodes  $D_{301}$  an  $D_{302}$  (1S1555) produce a DC voltage which is amplified by noise pulse amplifier  $Q_{303}$  (2SK19GR).

Under normal conditions,  $Q_{303}$  conducts, producing the cut-off voltage to the base of gate controller  $Q_{304}$  (2SC372Y); in turn, the high collector voltage of  $Q_{304}$  is supplied from pin 15 to the gate diode  $D_{109}$  (1S1007) in the RX RF unit, which conducts to pass the signal freely. With pulse noise,  $Q_{304}$  conducts, and its collector voltage drops, causing the gate diode  $D_{109}$  to disconnect the IF signal during the noise pulse duration.

#### AF AMP UNIT (PB-1764)

The audio signal is pre-amplified in the SSB IF unit and fed through pin 13 to the audio amplifier stage consisting of  $Q_{402}$  (2SC372Y),  $Q_{403}$  (2SC711),  $Q_{404}$  (2SA695),  $Q_{405}$  (2SD359), and  $Q_{406}$  (2SB-529). The audio power amplifier uses OTL (output transformerless) circuitry, and delivers 2 watts output to the speaker from pin 8.

In the FM mode, the squelch voltage is applied from pin 12 to the squelch controller  $Q_{401}$ (2SC372Y), which conducts when only noise (no signal) is present; in turn, the audio input is grounded to quiet the audio amplifier. When the signal is present,  $Q_{401}$  is cut off, and the audio amplifier operates normally. DC voltage is also applied from pin 12 to quiet the audio amplifier when the PLL circuit is unlocked.

A portion of the microphone input is delivered to pin 2 of the printed board. The speech signal is amplified by  $Q_{407}$  and  $Q_{408}$  (both 2SC372Y) and is applied to the base of  $Q_{409}$  (2SC373), which conducts with the speech signal, causing the collector to reach the "low" state. When a speech signal is not present,  $Q_{409}$  cuts off, and the voltage across  $C_{424}$  becomes "high".



AF AMP UNIT

 $C_{424}$ ,  $VR_{401}$ ,  $R_{437}$ , and  $R_{434}$  form the delay circuit to adjust the VOX relay hold time. The collector voltage is applied to NAND gate  $Q_{415}$ (MC14011B), causing pin 8 to become "high". When pin 8 and pin 9 are "high", pin 10 of  $Q_{415}$ becomes "low", causing  $Q_{410}$  (2SC373) to cut off; in turn, relay controller  $Q_{411}$  (2SC735) actuates the VOX relay.

The antitrip circuit provides a bucking voltage to prevent the speaker output from tripping the transmitter. The receiver audio output is connected through ANTITRIP potentiometer VR<sub>402</sub> to the antitrip amplifier Q<sub>414</sub> (2SC372Y). Amplifier Q<sub>413</sub> (2SC373) will conduct with the rectified voltage, thus keeping the potential at pin 9 of Q<sub>415</sub> "low", thus maintaning Q<sub>415</sub> in an "off" configuration while receiving.

The collector voltage of  $Q_{413}$  is also fed to the base of  $Q_{412}$ , which conducts with high collector voltage on  $Q_{413}$ , causing  $Q_{414}$  to become "high" rapidly for immediate relay actuation when a speech signal appears in the microphone circuit.

The tone oscillator  $Q_{418}$  (2SC373) operates when the MODE switch is in the CW position. It is a phase shift oscillator, operating at approximately 800 Hz.

The tone output is activated by the keying circuit through the emitter circuit of  $Q_{418}$ . It is coupled through sidetone level control VR<sub>403</sub> to the receiver audio amplifier  $Q_{403}$  for sidetone monitoring on CW. The output from  $Q_{418}$  is also coupled to the VOX amplifier  $Q_{408}$  for semi-break-in CW operation. In the FM mode, a DC voltage at the discriminator output is applied from pin 17 to the differential amplifier  $Q_{416}$  and  $Q_{417}$  (2SK19GR).

When the frequency of the received signal is shifted from the discriminator center, the resulting DC voltage causes either  $Q_{416}$  or  $Q_{417}$  to conduct, and the amount of shift is displayed on the meter when the meter switch is in the DISC position. VR<sub>404</sub> balances the differential amplifier, and VR<sub>405</sub> calibrates the sensitivity of the meter.

## TRANSMITTER

#### MIC AMP (UNIT PB-1753)

The speech signal from the microphone is fed from pin 23 to the first microphone amplifier  $Q_{502}$ (2SC1000GR). The input impedance of the microphone amplifier is 600 ohms. This signal is controlled in amplitude by the MIC GAIN control between pins 27 and 20, and is amplified by the second microphone amplifier  $Q_{503}$  (2SC1000GR), and applied to emitter follower  $Q_{504}$  (2SC372Y) to be delivered to the ring modulator  $D_{507} - D_{510}$ (1S1007).

The carrier oscillator  $Q_{507}$  (2SC372Y) oscillates at 10.7015 MHz for LSB, 10.6985 MHz for USB, and 10.6993 MHz for AM/CW, depending on the position of the MODE switch. In the CW position, the carrier oscillator oscillates at 10.6993 MHz for transmit and 10.6985 MHz for receive, producing an 800 Hz beat note in the receive mode. In the AM mode, the carrier oscillator does not function on receive. The MODE switch selects the crystal by means of a diode switch. The output from the oscillator is fed through the buffer amplifier Q508 (2SC372Y) to the balanced ring modulator  $D_{507}$ —  $D_{510}$  (1S1007). The carrier signal output from the buffer amplifier Q508 is fed from pin 20 to the SSB IF unit for SSB and CW reception. Carrier balance is obtained with potentiometer VR505 and trimmer capacitor TC504. The double sideband, suppressed carrier signal is amplified by Q<sub>509</sub> (2SK19GR) and fed from pin 17 to pin 5 of the SSB IF unit. In the AM and CW modes, the balanced modulator is unbalanced by the DC voltage applied from pin 13, and the carrier sgnal is fed through T<sub>502</sub> to carrier amplifier Q<sub>506</sub> (2SC372Y). The amplified carrier is fed from pin 3 to the EX-CITER unit.

The audio signal output from  $Q_{504}$  is fed from pin 22 to pin 12 of the EXCITER unit to be amplified to a sufficient level for low level amplitude modulation.

In the FM mode, the speech signal delivered to pin 23 of the MIC AMP unit is amplified by  $Q_{502}$  (2SC1000GR) and  $Q_{501}$  (TA7061AP), a limiter amplifier, and is fed through deviation control potentiometer VR<sub>502</sub> (narrow) or VR<sub>503</sub> (wide) to pin 7 of the TONE BURST unit. Here it is amplified through an active low-pass filter circuit,  $Q_{1104}$ 

(2SC1000GR), which attenuates all audio frequency components above 2700 Hz. The signal is further amplified by  $Q_{1105}$  (2SC1000GR) and applied to the modulator, varactor diode  $D_{501}$ (FC63). The frequency modulated signal is then amplified by  $Q_{506}$  (2SC372Y) and fed through a diode switch to the EXCITER unit.

## **EXCITER UNIT (PB-1762)**

The SSB output signal from the SSB IF unit, as well as the AM, CW, and FM output signals (10.7 MHz) from the MIC AMP unit, are fed to the EX-CITER unit from pin 3 and pin 5, respectively.

The 10.7 MHz signal is fed to the balanced mixer consisting of  $Q_{601}$  and  $Q_{602}$  (2SK19GR), where the signal is mixed with the 133.3 to 137.3 MHz heterodyne signal delivered from pin 4 of the printed board, thus producing a 144—148 MHz signal. The output signal from the balanced mixer

passes through the tuned circuits consisting of  $T_{602}$ and  $L_{601}-L_{603}$ , which are tuned by varactor diodes  $D_{601}-D_{604}$  (1S2209), in which voltages are preset in accordance with the position of the bandswitch. Thus, the circuit is tuned exactly to the operating frequency, and spurious radiation is effectively eliminated. The signal is then amplified by the amplifier chain consisting of  $Q_{603}$  (2SC784R),  $Q_{604}$  and  $Q_{605}$  (2SC2053), and  $Q_{606}$  (2SC730), and delivered from pin 17 to the BOOSTER unit.

The DC voltage for  $Q_{601}$  through  $Q_{604}$  is supplied through  $Q_{609}$  (2SC735Y). When the PLL circuit is unlocked, the controller transistor  $Q_{610}$  (2SC372Y) stops conducting, and in turn  $Q_{609}$  stops supplying DC voltage for  $Q_{601}$ — $Q_{604}$ .

The speech signal from pin 22 of the MIC AMP unit is fed through the AM amplifier  $Q_{607}$  (2SC373) and emitter follower  $Q_{608}$  (2SC372Y) to the AM modulator  $Q_2$  (2SD213D), which controls the supply voltage for  $Q_{606}$  (2SC730).



#### **BOOSTER UNIT (PB-1744, PB-1745)**

The signal from the EXCITER unit is fed to the BOOSTER unit and amplified by the driver amplifier  $Q_{701}$  (MRF212) and the final amplifier  $Q_{702}$  (2N5591), which delivers 25 watts of RF power to the antenna through a two-stage low-pass filter.

The bias voltage is stabilized at 9 volts by zener diode  $D_{701}$  (1N4732). Two diodes,  $D_{702}$  and  $D_{703}$  (both 10D1), are used to protect the final transistor from damage due to heating by reducing the bias voltage when the temperature rises. A small portion of the RF output is rectified by a diode  $D_{712}$  (1S188FM), which delivers the resulting DC voltage to the meter, where an indication of the relative power output is provided.

The DC voltage obtained from rectifying a small portion of the RF output by the ALC diodes  $D_{707}$  and  $D_{708}$  (1S1555) is applied to the gate of  $Q_{207}$  in the SSB IF unit and  $Q_{509}$  in the MIC AMP unit. Diodes  $D_{707}$  and  $D_{708}$  are biased by the ALC threshold control VR<sub>703</sub>. Thus, the gain of  $Q_{207}$  and  $Q_{509}$  is controlled in order to control automatically the driving level to the PA transistor, in order to prevent any distortion caused by overdrive.

Blocking diodes  $D_{714}$  and  $D_{715}$  disconnect the supply voltage to  $Q_{702}$  while the antenna is disconnected for marker calibration (analog model).

## TONE BURST UNIT (PB-1752)

When the PTT switch is activated, a DC voltage is applied to trigger  $Q_{1101}$  (F-4011), which generates a pulse of duration 0.5 — 1 second. The pulse switches  $Q_{1103}$  (2SC372Y) to supply DC voltage to  $Q_{1102}$  (MSM5576), where the clock signal is divided by 1024, 2048, or 4096, producing an accurate tone burst frequency. The burst signal is fed to the base of the MIC amplifier  $Q_{1104}$  (2SC-1000GR).

The tone duration is set by  $VR_{1101}$ , and the tone level is set by  $VR_{1102}$ .

The exact tone frequency is determined by a crystal and the plug position, as described in the OPERATION section.

In the European model, the tone burst signal is activated by depressing the BURST switch.





#### COMMON CIRCUITS

The FT-225RD utilizes a phase locked loop (PLL) system for the heterodyne oscillator, which provides a stable signal varying from 133.3 to 137.3 MHz, thus providing coverage of the entire 2 meter band.

#### VFO UNIT (PB-1774)

The VFO module board is installed in the VFO chassis. The VFO (variable frequency oscillator)  $Q_{1301}$  (2SC372Y) generates an 8,200 to 9,200 kHz signal, thus producing a 1 MHz tuning range. Frequency drift is minimized through the use of a temperature compensation circuit utilizing a differential trimmer capacitor. The signal is fed through the amplifier buffer stage  $Q_{1302}$  (2SK19GR) and  $Q_{1303}$  (2SC372Y) to pin 3 of the FIX oscillator board. The buffer amplifier provides isolation and amplification of the VFO signal.



VFO UNIT



FIX UNIT

#### FIX UNIT (PB-1750)

In addition to VFO or optional memory operation, 11 crystals may be employed for crystal controlled operation with the selector switch located on the front panel.

The FIX channel crystal oscillator  $Q_{901}(2SC372Y)$  oscillates at the frequency of the crystal selected by the diode switch  $D_{101} - D_{111}$  (1S1555). The output is fed from pin 8 through the buffer amplifier  $Q_{902}$  (2SC372Y) to the PLL UNIT.

The signal from the VFO also passes through this buffer stage and through jumper  $J_{26}$  or the memory unit to the PLL unit.

The crystal frequency falls between 8,200 kHz and 9,200 kHz, and is determined by the formula  $f_x = f_0 - f_1$  where  $f_x$  is the crystal frequency,  $f_0$  is the operating frequency, and  $f_1$  is a constant found in Table 3 on page 14.

#### LOCAL UNIT (PB-1805)

The local oscillator generates a heterodyne signal which is used to convert the VCO (voltage controlled oscillator) signal into an 8,200 - 9,200 kHz signal; this is used for the comparison of the phase with that of the reference VFO signal.

The crystal controlled oscillator  $Q_{801}$  (2SC372Y) oscillates at the fundamental frequency of the crystal. A varactor diode  $D_{813}$  (1SV50), connected to the base of  $Q_{801}$ , is used as a clarifier to shift the oscillator frequency for offset tuning.

The output from the oscillator is fed to the frequency multiplier stage  $Q_{802}$  and  $Q_{803}$  (both 2SC784R), producing the ninth harmonic at its output. The crystal is selected by a diode switch connected to the bandswitch. The relation between the frequency and band is shown in Table 1. The multiplied signal is then fed from pin 33 to the PLL unit.

For repeater operation, a fundamental crystal at 14.0555 MHz,  $X_{807}$ , is used to generate a heterodyne signal of 126.5 MHz, when the bandswitch is set to the 144, 145, or 146 MHz bands.  $X_{808}$  (fundamental frequency 14.300 MHz) is used to generate a 128.7 MHz signal, which is 600 kHz higher than the normal heterodyne signal, when the bandswitch is set to the 147 MHz band. A relay,  $RL_{1101}$ , which is located on the TONE BURST unit, is used to select the above crystals when the RPT switch  $S_{1505}$  is activated.

When the RPT switch is in the NOR position, the crystals are selected as above. When the RPT switch is placed in the REV position, the receive frequency is shifted down in the 144, 145, and 146 MHz bands, and the receive frequency is shifted up in the 147 MHz band. In the REV position, the analog dial indicates the transmit frequency, while the digital display indicates the receive and transmit frequencies properly.

## PLL UNIT (PB-1748)

The PLL unit generates a heterodyne signal for the transmitter and receiver mixer in conjunction with the phase locked oscillator.

A voltage controlled oscillator  $Q_{1001}$  (2SK19GR) generates a signal between 133.3 and 137.3 MHz, which is determined by  $L_{1002}$  and  $D_{1001}/D_{1002}$ (both 1S2208). The output from  $Q_{1001}$  is fed through a two-stage buffer amplifier consisting of  $Q_{1002}$  and  $Q_{1004}$  (both 3SK40M), to the mixer  $Q_{1005}$  (2SC784R), where the signal is mixed with the 125.1 MHz signal delivered from the local oscillator, thus producing an 8.2–9.2 MHz comparison signal.

NO. 10



PLL UNIT

LOCAL OUT

003

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The comparison signal is amplified by  $Q_{1006}$  and  $Q_{1007}$  (both 2SC372Y), and the wave is shaped by  $Q_{1014}$  (SN75450B). The output of  $Q_{1014}$  is fed to a phase comparator  $Q_{1009}$  (MC4044P), which compares the phase of the comparison signal against that of the reference signal, and any difference is converted into an error correcting DC voltage. The DC voltage is amplified by  $Q_{1002}$  to control the frequency of the VCO.

When the VCO is unlocked, the pulse signal appearing at pin 6 of  $Q_{1009}$  is rectified by  $D_{1004}$  and  $D_{1005}$  (both 1S1555). The rectified DC voltage is amplified by  $Q_{1014}$  and fed to the counter unit to turn the LED's off, indicating that the VCO is unlocked.

The DC voltage switches  $Q_{401}$  in the AF AMP unit to quiet the receiver when the PLL is unlocked. In transmit, this voltage switches  $Q_{610}$  in the EX-CITER unit to turn the transmitter off.

#### OSC UNIT (PB-1761) (Digital model only)

The unit is installed in the digital model to produce a 129.3 MHz heterodyne signal for the counter. A crystal controlled oscillator  $Q_{1701}$  (2SC373) oscillates on 14.3667 MHz, and its output is multiplied 9 times by triplers  $Q_{1702}$  and  $Q_{1703}$  (both 2SC710), producing the 129.3 MHz heterodyne signal. The diode switch connected in series with crystal  $X_{1701}$  compensates the frequency when changing modes.

COUNTER UNIT (PB-1734, PB-1735)

The frequency of operation is indicated in MHz, kHz, and to 100 Hz resolution by seven large LED's.

The heterodyne signal for the counter is delivered to pin 5 from the PLL unit, and amplified by  $Q_{1801}$  (2SK19GR). It is then fed to the double balanced mixer  $Q_{1802}$  (SN76514), where the signal is mixed with the 129.3 MHz heterodyne signal, producing a 4 to 6 MHz signal at its output.

The 4 – 6 MHz signal is amplified by  $Q_{1803}$  (2SC-784R) and fed through a waveform shaper  $Q_{1804}$  (2SC372Y) to a counter gate  $Q_{1806}$  (F4011), which counts the pulses which pass while the gate is opened. The pulses are fed to the six digit decade counter  $Q_{1808}$  (TC5032P), which counts 100 Hz, 1 kHz, 10 kHz, 100 kHz, and 1 MHz. The BCD output signal from  $Q_{1808}$  is fed through LED dimmer  $Q_{1818}$  (MSM561) and  $Q_{1811} - Q_{1817}$  (all 2SC496) to the display LED's,  $Q_{1822} - Q_{1828}$  (all HP 5082–7740).  $Q_{1819} - Q_{1821}$  (SN75453) work as a series of switches operated by a timing signal delivered by  $Q_{1808}$  to select the output of  $Q_{1808}$  which drives the display in the sequence 100 Hz, 1 kHz, 10 kHz, 100 kHz, 1 MHz.

When the unlock signal is received from the PLL unit,  $Q_{1809}$  (2SC372Y) and  $Q_{1810}$  (2SA496) generate a blanking signal to the LED driver.

Q2001 T2001



**VFO BUFFER UNIT** 



COUNTER UNIT



OSC UNIT

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#### MARKER UNIT (PB-1802) (Analog model only)

The crystal marker generator  $Q_{2101}$  (2SC372Y) generates a 12.8 MHz signal, and its output is fed through buffer amplifier  $Q_{2102}$  (2SC372Y) to frequency divider  $Q_{2103}$  (34024PC), where the 12.8 MHz signal generates a 100 kHz marker signal. The marker signal is fed through a buffer amplifier  $Q_{2104}$  (2SC372Y) to the RX RF unit. When the marker switch is activated, the antenna relay is actuated, disconnecting the antenna.



MARKER UNIT



REG UNIT

#### POWER SUPPLY & REGULATOR UNIT (PB-1469)

The power supply has been designed to operate from 100/110/117/200/220/234 V AC 50/60 Hz, or 12 V DC, negative ground. Inserting the appropriate power cord into the rear panel receptacle makes the necessary connections for operation from an AC or DC supply.

For AC operation, the DC voltage is supplied from the bridge rectifier unit  $D_2$  (S15VB10), which is connected to a 20 volt, 6 amp secondary winding of the power transformer. The DC voltage is regulated at 13.6 volts by the voltage regulator circuit consisting of  $Q_{1401}$  (2SD313D) and  $Q_1$  (MJ802).

Since such circuits as the VFO, local oscillator, and PLL require an extremely stable voltage, the 13.6 V DC supply is further stabilized at 8 volts by voltage regulator  $Q_{1404}$  ( $\mu$ PC14308).  $Q_{1403}$  (2SC372Y) switches to disable the voltage regulator (consisting of  $Q_1$  and  $Q_{1401}$ ) when the current exceeds the preset value.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4 of power receptacle  $J_1$ . To protect the circuits from reversed polarity of the DC voltage,  $D_1$  (U05B) conducts heavily under reversed polarity conditions to blow the line fuse in the DC cord. It is placed between pin 3 and ground on  $J_1$ .



REG UNIT (PB-1756)

# MAINTENANCE & ALIGNMENT

## GENERAL

Your FT-225RD transceiver has been carefully aligned and tested at the factory prior to shipment. The reliability of the solid-state devices used in the FT-225RD should provide years of trouble-free service if the transceiver is not abused, and if routine maintenance is carried out.

The following precautions should be observed, so as to prevent damage to the transceiver:

- (1) Do not interchange the AC and DC power cords.
- (2) Do not apply any AC voltage other than that voltage determined by the transformer primary winding.
- (3) When replacing fuses, be certain to use a fuse of the proper rating for the voltage being used.
- (4) Do not exceed 14 volts DC, at the POWER receptacle, for DC operation. When operating mobile, the battery voltage should be measured with the battery under load (transmitter "keyed" in the FM mode), with the engine running fast enough so that the ammeter shows a "charge". In addition, do not operate the FT-225RD if the supply voltage is less than 12 volts DC.
- (5) Avoid direct exposure to sunlight or water.

## ROUTINE MAINTENANCE

Routine maintenance should be limited to keeping the transceiver clean, and performing occasional performance checks of the transmitter RF power output and the receiver sensitivity.

#### Cleaning:

When the transceiver has been used in a dusty or sandy environment, the interior should be cleaned periodically. A vacuum cleaner or low pressure air blower should be used.

Accumulated dirt may be removed with a soft brush. Check that the interior is thoroughly dry before replacing the cabinet and/or operating the equipment. Wipe the exterior with a damp cloth when necessary.

## PERFORMANCE CHECKS

Make all performance checks at 13.6 volts DC (under load), or on the appropriate AC voltage as determined by the transformer primary wiring.

#### Check the transmitter as follows:

- (a) Connect a suitable 50 ohm dummy load/RF wattmeter to the ANT receptacle.
- (b) Set the MODE switch to the FM position, and key the transmitter while observing the power output, which should be approximately 25 watts. At full power, the S-meter should indicate between 6 and 8 on the relative power output scale.
- (c) Set the MODE switch to SSB, and key the transmitter. Speak in a normal voice into the microphone. The output meter should indicate between 3 and 5 nominally.

#### Check the receiver sensitivity as follows:

- (a) Connect an AC VTVM to the SP jack. Set the MODE switch to the FM position, and set the SQUELCH control fully counterclockwise.
- (b) Connect the RF output of a precision VHF signal generator to the ANT receptacle and note the VTVM reading with no signal input. Adjust the AF GAIN control and the VTVM range, as required, to obtain a full scale VTVM reading. Do NOT change the setting of the AF GAIN control after this calibration has been made.
- (c) Set the signal generator to the receiving frequency of the transceiver, and adjust the output amplitude of the signal generator until the VTVM reads 1/100th (20 dB decrease) of the reading in step (b). The signal generator output voltage at this point is the 20 dB quieting sensitivity, and it should be approximately  $0.35 \,\mu$ V.
- (d) Set the MODE switch to SSB, and connect the AC VTVM to the speaker output. Apply an unmodulated 0.5  $\mu$ V signal from the signal generator, and tune the transceiver tuning dial for a maximum VTVM reading.
- (e) Advance the RF Gain control to the fully clockwise position, and adjust the AF GAIN control for a reading of 450 mV on the VTVM.

(f) Reduce the signal generator output, and read the VTVM; the VTVM reading should be less than 45 mV for a 10 dB S/N ratio.

If the above checks indicate a need for realignment, it is recommended that the unit be returned to the dealer for this procedure. Alignment requires special test equipment not normally available to the average station owner. Adjustment of the tuned circuits without the proper equipment or technical expertise will result in degraded transceiver performance.

#### ALIGNMENT

SOME OF THE FOLLOWING ALIGNMENT PROCEDURES REQUIRE SPECIAL TEST EQUIPMENT AND TECHNICAL KNOWLEDGE, AND SHOULD ONLY BE ATTEMPTED BY AN EXPERT TECHNICIAN.

#### AF AMP UNIT (PB-1764)

(1) CW Semi-break-in

Adjust  $VR_{401}$ , the DELAY control, for the desired relay hold time.

(2) CW Sidetone Level

Adjust VR403 for the desired sidetone level.

(3) Antitrip

Set the ANTITRIP control,  $VR_{402}$ , to the minimum point that will prevent the speaker output from activating the VOX. The DELAY control,  $VR_{401}$ , may be adjusted for the desired relay hold time.



TOP VIEW

## (4) Discriminator Center Meter

Set the controls as follows: CHANNEL . . .VFO MODE. . . . . .FM DISC . . . . . .OFF (S-meter position) RF GAIN . . . .Fully clockwise MARKER . . . .ON (Analog model; for RD, connect signal generator to antenna receptacle)

Tune the transceiver for a maximum S-meter reading on the marker or signal generator signal. Tune the main dial so as to find the center of the maximum signal indication. Place the meter switch in the DISC position, and adjust the center potentiometer VR<sub>404</sub> so that the meter pointer is exactly at midscale on the meter. Check to see that the meter moves an equal amount on either side of the center for an equal frequency excursion. Shift the VFO frequency 10 kHz lower than the reference signal, and adjust the DISC potentiometer, VR<sub>405</sub> for a meter reading of 2 on the DISC scale.



AF AMP UNIT (PB-1764)



#### BOTTOM VIEW

## MARKER UNIT (PB-1802) (Analog model only)

## (1) Frequency Adjustment

Connect a frequency counter, through a 100 pF capacitor, to the collector of  $Q_{2102}$  (2SC372Y). Adjust TC<sub>2101</sub> to set the crystal frequency exactly to 12.800 MHz. If a frequency counter is not available, use an external HF receiver, and zero the 100 kHz marker signal against WWV or JJY.

## CW KEYING UNIT (PB-1751)

## Voltage Adjustment for the Varicap Tuning Circuit

Measure the voltage at pins 2, 3, 4, 5, 14, 15, 16, and 17, with the VTVM connected between ground and the pin under test.

Adjust the appropriate potentiometer,  $VR_{1201}$  —  $VR_{1208}$ , for the following pin voltages.

	BAND	VOLTA	GE	
VR 1201	144	2.5 V		
VR 1202	145	3.5 V		
VR 1203	146	4.5 V		
VR 1204	147	5.5 V		
VR 1205	144 RPT	1.9 V	*	TX-600kHz shift
VR 1206	145 RPT	2.9 V	*	"
VR 1207	146 RPT	3.9 V	*	"
VR 1208	147 RPT	5.9 V	*	TX+600kHz shift

TUNE control 12 O'clock

★ US model



MARKER UNIT (PB-1802)



VR1210 VR1209

CW KEYING UNIT (PB-1751)



CW KEYING UNIT

#### SSB IF UNIT (PB-1778)

## (1) S-Meter Setting

Disconnect the antenna from the coax receptacle. Set the MODE switch to the AM position, and set the RF GAIN control to the fully clockwise position. Adjust VR201 ("ZERO") until the meter indicates zero. Then set the RF GAIN control fully counter-clockwise. Adjust VR202 ("FULL SCALE") until the meter reads full scale. Return the RF GAIN control to the fully clockwise position, and connect a signal generator to the antenna receptacle. Set the output of the signal generator to 144.5 MHz with an output of 0 dB, and tune the receiver to the generator signal. Place the TUNE control in the 12 o'clock position, and adjust VR<sub>203</sub> for a reading of S3 on the S-meter. Repeat the above procedures until the full scale, zero, and S3 readings are achieved for the above settings.

## MIC AMP UNIT (PB-1753)

#### (1) SSB Carrier Frequency

Connect a 50 ohm dummy load, such as the Yaesu YP-150, to the antenna receptacle, and connect the output of an audio oscillator to the microphone input. Set the MODE switch to an SSB mode. Apply a 1 kHz audio signal to the microphone input, and adjust the SSB MIC GAIN control or the audio oscillator output for an RF output of 10 watts as indicated on the wattmeter. Change the audio frequency to 350 Hz, and adjust  $TC_{503}$  for LSB and  $TC_{502}$  for USB to obtain 2.5 watts output. Change the audio frequency to 2600 Hz; the RF output should be 2.5 watts.

#### (2) AM and CW Carrier Frequency

Tune the transceiver in the USB mode into a dummy load, and use another receiver to monitor the transmitted signal. Tune the external receiver until the transmitted voice quality is natural. Change the FT-225RD to AM (leave the external receiver in the USB mode), and adjust  $TC_{501}$  for a zero beat as heard in the external receiver.

#### (3) Carrier Balance

Connect a dummy load to the antenna receptacle, and the RF probe of a VTVM to the center conductor of the antenna receptacle. Set the MODE switch to LSB. Set the SSB MIC GAIN control to the fully counter-clockwise position, and set the VOX GAIN switch to the MOX position. Adjust VR<sub>505</sub> and TC<sub>504</sub> ("CARRIER BALANCE") alternately to minimize the VTVM reading.

Repeat this procedure on USB, then repeat the procedure, so that a minimum reading is obtained on both sidebands.

#### (4) CW Carrier Level

Set the CW level control,  $VR_{507}$ , to the point where the RF output no longer increases when the control is advanced.



MIC AMP UNIT (PB-1753)

## FIX UNIT (PB-1750)

Precise frequency alignment of the fixed channel crystals may be made by adjusting  $TC_{901} - TC_{911}$ .



FIX UNIT (PB-1750)

## RX RF UNIT (PB-1746)

Set the BAND switch to 144, the CHANNEL switch to VFO, the RF GAIN control fully clockwise, and the MODE switch to USB. Tune the VFO to a 10 dB signal at 144.500 MHz from a signal generator connected to the antenna receptacle. Peak  $TC_{101}$ ,  $TC_{102}$ ,  $TC_{103}$ , and  $TC_{104}$  for a maximum S-meter reading. If the majority of your operating is done in the upper part of the band (146 — 148 MHz), it is recommended that this alignment be performed on 146.5 MHz.



# EXCITER UNIT/BOOSTER UNIT (PB-1762), (PB-1744), (PB-1745)

#### (1) Power Output

It is recommended that an insulated alignment tool be used for this alignment. Connect a dummy load to the antenna receptacle. Set the BAND switch to 145, the CHANNEL switch to VFO, and the MODE switch to FM. Set the VFO to 145.00 MHz, and set the VOX GAIN control to the MOX position. Peak  $TC_{601} - TC_{609}$  and  $TC_{701} - TC_{704}$ for maximum power output.

Change the frequency to 144.1 MHz and repeat the above procedures for maximum power output. Change the frequency to 147.9 MHz and repeat the above procedures for maximum power output.

Repeat the above alignments alternately on 144.1, 145.0, and 147.9 MHz until unity power output is obtained across the band.

## (2) PO Meter Set

The PO (Power Output) meter indicates relative power output. After completion of the above power output alignment, set the meter control  $VR_{704}$  to the point where the meter pointer indicates 80% of full scale at full output.

### (3) AM Carrier Level

Set the MODE switch to AM. Adjust  $VR_{602}$ , in the EXCITER UNIT, for 8 watts unmodulated carrier output into a dummy load.

## (4) ALC Threshold

Connect the output from a two-tone signal generator to the microphone input, and connect a dummy load/wattmeter to the antenna receptacle. Set the BAND switch to 145, the CHANNEL switch to VFO and the MODE switch to USB. Set the VOX GAIN control to the MOX position. Apply a 1 kHz single tone signal to the microphone input, and adjust the signal generator output until the power meter shows 2.5 watts. Then apply a 1.5 kHz tone, and adjust its level to produce 2.5 watts output. Leaving these levels at the preset position, apply the 1 kHz/1.5 kHz two-tone signal, and adjust VR<sub>703</sub> for a power output of 3 watts.

RX RF UNIT (PB-1746)



## TONE BURST UNIT (PB-1752)

The burst signal is automatically transmitted when the PTT switch on the microphone is keyed, and when the BURST button is depressed. The length of the burst signal is preset at the factory for approximately 0.5 second. Adjustment of the burst length is made by VR1101. Clockwise rotation increases the length of the burst.



TONE BURST UNIT (PB-1752)

## LOCAL UNIT (PB-1805)

Set the MODE switch to USB, the BAND switch to 144.0, and the CHANNEL switch to VFO. Connect a frequency counter to pin 33 of  $J_{13}$ . Adjust  $L_{801}$  to 125.1 MHz ±100 Hz. Set the BAND switch to 145.0, and adjust TC<sub>802</sub> to 126.1 MHz ±100 Hz. In like fashion, adjust TC<sub>803</sub> for 127.1 MHz ±100 Hz for 146.0 MHz, and TC<sub>804</sub> to 128.1 MHz ±100 Hz for 147.0 MHz.

Set the RPT switch to NORM, the AUX/600 kHz switch to 600 kHz, and the BAND switch to 144.0 MHz, and adjust TC<sub>806</sub> to 125.5 MHz  $\pm$ 100 Hz. Likewise, adjust TC<sub>807</sub> to 126.5 MHz  $\pm$ 100 Hz for 146.0 MHz, and TC<sub>808</sub> to 127.5 MHz  $\pm$ 100 Hz for 147.0 MHz.

Disconnect the frequency counter and connect it to pin 5 of  $J_{12}$ . Adjust the main tuning dial for a reading of 8200 kHz on the frequency counter. Set the analog sub-dial to zero. Adjust TC<sub>1802</sub> on PB-1761 until the digital display reads 144.0015 MHz, making sure that the MODE switch is still on USB Adjust TC<sub>1801</sub> for a reading of 143.9985 with the MODE switch on LSB: adjust TC<sub>1804</sub> for a reading of 144.0000 on FM; adjust TC<sub>1803</sub> to 143.9993 MHz on CW, transmit mode.

#### **PLL UNIT (PB-1748)**

This unit does not require any adjustment unless major components are changed, and if this happens, precise measuring equipment is required for alignment. The following simple alignment can, though, be made:

Turn the transceiver to 144.0000 MHz. Connect a VTVM DC probe to  $C_{1049}$  (feedthrough capacitor) and adjust TC<sub>1001</sub> for a reading of exactly 1.75 volts on the VTVM. Check to see that the PLL circuit locks at all frequencies.



LOCAL UNIT (PB-1085)







FM IF UNIT (PB-1463)

## SQUELCH THRESHOLD

Disconnect the antenna from the receptacle. Set the BAND switch to 144, the CHANNEL switch to VFO, the RF GAIN control fully clockwise, the MODE switch to FM, and the SQUELCH control to the 9 o'clock position. Adjust VR<sub>6</sub> to the point where the receiver is just silenced. Do not go beyond this threshold point, or the SQUELCH control will not function properly.

## **FM DEVIATION ADJUSTMENT**

Connect a dummy load and an FM deviation meter to the antenna receptacle, and connect the output of an audio oscillator to the microphone input. Set the MODE switch to FM and the VOX GAIN control to MOX. Set  $VR_{501}$  to the fully clockwise position, and  $VR_{504}$  to the center of its range.

Apply a 1 kHz 3 mV audio signal to the microphone input. Observe the wave form on the oscilloscope display which is connected to a frequency deviation meter. Adjust  $VR_{504}$  until a sine wave is obtained in the scope pattern.

Connect a frequency counter to pin 3 of the MIC AMP UNIT and disconnect the audio signal input to the microphone input. Adjust  $L_{501}$  until the oscillating frequency becomes exactly 10.7 MHz. Connect the audio generator to the microphone input again, and adjust the input level until +5 kHz deviation with a sine wave pattern is obtained. If a sine wave is not\_obtained, repeat the above procedures. Increase the input level to 25 mV, and adjust VR<sub>502</sub> for +5 kHz deviation.



SG S S Q1811 ~1817 Q1810 Q1820 Q1809 Q182 Q1808 Q1807 Q1818 Q1804 Q1806 Q1803 Q1805 T1803 X1801 Q1802 Q1801 T1802 T1801

COUNTER UNIT (PB-1735, 1803)



OSC UNIT (PB-1761)
ie.		IN CHASSIS					METER	
Symbol Number	Parts Number	Descr	ription		M1 (with PL3)	74000370	SP-38A	
		IC & TRANSISTO	R					
Q3	25000116	IC		μPC14308				
Q4	25000109	"		µPC14305				
Q1 W/Insulator	22490003	Transistor		MJ802			SPEAKER	
Q2	22403134	*		2SD313D	SP1	76000017	4Ω 3W SA-77	WV .
46	22403134			2303130	511	7000017	442 3W SA-11	K I
		DIODE					RELAY	
D1	21090130	Silicon Diode		U05B	RL1	7000005	AE-3171-42	
D3~D19	21090011	"		10D1				
D2	21090144	*		S15VB10				
							RELAY SOCKET	
					RLS1	69000004	AE-3860	
		RESISTOR						
R8	41143223	Carbon Film	1/4 W T	J 22KΩ				
R2	42124100	Carbon Compos						
R7				× 22Ω			SWITCH	
	42124220		· · ·		C1	61000100	SWITCH	00001
R1	42124101			× 100Ω	S1	64000490	Ale and a second se	2020N
R5	42124102		, ,	» 1KΩ	S2,4	64000520	"	2064N
R4	42124562		, ,	≈5.6KΩ	S3	64000510	"	4085N
R6	42124154	"	, ,		S5	64000200	*	SP-2022
					P1	68130002	PLUG	5047 12
		DOTENTIONETED						5047-13 #240057A
UD1 A		POTENTIOMETER			P2	68100012		5047-10 #240058
VR1,3	49900098	DM10A041		2B /10KΩA <sup>*</sup>	P3	67040002		SI- 5908
VR2	49900099	DM10A04	1K	C·/100KΩB				
VR4	49900085	VM11A5M1112		10ΚΩΑ				
VR5	49900100	FVH BOAS25B	54	<b>50KΩB</b>				
VR9	49800045	EVH BOAS15B	54	50KΩB			CONNECTOR	
					J1	67040004		QMS-AB4M
					J2	68050003		CS-250
					J3	68020002		SG-7615
		CAPACITOR			J4	68020012		SG-8050
C1,2	30240472	Ceramic Disc	1.4KV	0.0047µF	1.1.1.1.1.1	68040003		FM-144J
C10,11,13~18,23~27		% %	50WV	0.004/µT	J6			SG-8018
C 29~33,36,38	30820102		50W V	0.001µF	10,000	68020013		
		11	2		J7~11	68020001		CN-7017J
C5~9,19,28,39	30820103	" "	"	0.01µF	J24	68090001		SB-7702
C12,34,35,37,40	30820473	* *	"	0.047µF	J25 with Wire	96000104		# 240030-
C20~22	35220476	Electrolytic	16WV	4.7µF	J26	67090002		1625-9R-1 # 240064
C4	35220228	"	16 W V	2200µF				
C3	34529001	*	35 W V	6800µF				
							MULTI JACK	
			-		119 14- 10 01	6000000	MOLTI JACK	0000 200 005
					J12,14~19,21	68360001	1	220D-36B- 205
2		01101/5			J13,20,22	68180003		121S-18B-105
0114		CHOKE						
CH1	55003001	SN-8S-500						
CH2	50000010	50-12		#230012				
							FUSE	
					F1	73000003	3A	
		POWER TRANSFO	RMER					
PT1	52000052	52-56		#230016				
							FUSE HOLDER	
					FH1	69030001	SN1001 #2	
-					FH2	69030007	F3265	

		LAMP					C190 192 195 196 190	20020102	Cerami	. D:	FOWI	0.001. F
PL1,2	14000018	BQ044-327	751 4				C120, 123, 125, 126, 129 C132, 133, 135, 144, 145	30820102	Cerami	c Disc	50W V	0.001µF
PL3 (Meter)		BG044-32					C132,133,135,144,145 C148,149,151					
PL3 (Meter)	_	BF 342-01	540A				C148, 149, 151 C127, 130, 131, 134, 136	30820103	"	"		0.01µF
							C127,130,131,134,130	30820103		~	1	0.0141
								26005 472				0.047
				_	_	-	C138	36825473	Mylar	*		0.047µF
- Instantion Acad			-				C139	34220105	Electro	lytic	16W V	lμF
Symbol Number		RF unit	)ocori	iption								
PB-1746	Parts Number 60417460	Printed C			1							
FD-1740	017460AZ											
	017400AZ	FCD with	com	ponents			and the second second					
						-			TDIMMED	CADA	CITOR	
							TC101~104	39000006	TRIMMER		0×40	10PF
		FET & TRAM	ICICT	OP			TC101 - 104	3900000	ECV1Z		0×40 0×53	10PF
Q102,103	23800510	MOS FET		UR	25	K51	1,0105	3900010		1	0~55	IUFF
Q102,103	22307842	Silicon T	_	stor		C784R		-				
Q104 - 100	22301042	Silicon I	ransis	stor	23	C704R						
									INDUCTOR			the second s
Λ							L103	55003251	THEOUTOR			# 220316
		DIODE					L103	55003251				# 220316
D109	21010070	Germaniur	n D	iode	19	1007	L104,106	- Constant of the Second				**************************************
D109		Silicon	n D	iode #		C301	L105 L110 (R138)	55003253 55003254	DE CU	OVE		# 220318 # 220310
D105~108,110	21090142 21022090	Varactor		"		2209	L110 (R138) L109,111		RF CH Micro	0.010.000.000		
5105-108,110	21022090	varactor		"	15	2209	L109,111 L112,113	53020007 53010003	Micro //	Inducto	n.	FL-5H 22µH 250µH
							1112,113	53010003	~	"		250¢H
										-		
		CRYSTAL FI		,								
XF101,102	71000025	10M2A-2							TRANSFOR			
AF 101,102	71000025	IUMZA-2					T101~104	55003083	3005	OVIER		# 220187
							24.5			00		# 220187
							T105	54141020	R12-41	02		# 220111
		DESIGTOD										
R118	40143560	RESISTOR Carbon Fi	ilm	1/4 W	VJ	56Ω						
R114,117,125,129,136	40143560	- C-	// // //	74 W	VJ	100Ω			FERRITE			
R135	40143101		"	"	"		EDIAI	5000004				
	195 Stores and			N//		220Ω	FB101	56000024	RI	3	×3×1	
R103	40143271	100	*	"	*	270Ω		· · · · · ·			-	
R124	40143471		"	"	*	470Ω				_		
R101,102,104,105,128			"	"	"	1KΩ		0.00		_		
R132	40143152		*	"	"	1.5KΩ		SSB	<sup>3•</sup> IF unit			
R130	10143222		"	"	"	2.2KΩ	Symbol Number	Parts Number	Die		ription	
R131	40143392		"	"	"	3.9KΩ	PB-1778	60417780			it Board	
R133	40143472		"	".	"	4.7KΩ		017780AZ	PCB w	ith con	nponents	
R122,127	40143822	"	*	"	"	8.2KΩ						
R120,121,139	40143103	1	"	"	"	10KΩ						
R112,134	40143223	"	"	"	"	22KΩ				-		
R123,126	40143393	*	*	"	"	39KΩ	0000	0500000	IC, FET &	TRAN	ISISTOR	
R113,119	40143473		*	"	*	47KΩ	Q208	25000098	IC			TA7045
R109~111	40143104		*	"	"	100KΩ	Q209	25000152	*			μPC1037H
R115,116,137	40143105		"	"	*	1MΩ	Q202,207	22800195	FET	-		2SK19GR
R107,108	41143105		"	*	TJ	1MΩ	Q203,204	22303730	Silicon		and the second	2SC373
R138 (L110).	42104102	* Co	omposi	ition 1/4	W	1ΚΩ	Q205,206	22310006	"		"	2SC1000B
							Q201	22307842	"		"	2SC784R
								* ×			5	
		CAPACITOR							DIODE			
		Ceramic I	Disc	50W \	/ 1PF	SL	D201~203,206,209	21010070	German	ium I	Diode	1S1007
C150	31829010		"	"	3PF		D204	21001880	"		"	1S188FM
C124	31829010 31829030	*	"				D205	21015550	Silicon			1S1555
C124 C152	31829030 31829080		4	"	8PF		D205	21010000		1	"	151555
C124 C152 C114	31829030 31829080 31829300	"		" "	30PF	SL SL	D205	21019410	"	n *	"	1S1935
C124 C152	31829030 31829080	*	"	-		SL SL	1.200390300					
C124 C152 C114	31829030 31829080 31829300	*	4 4	"	30PF 47PF	SL SL	D207	21019410	"	"	"	1S1941
C124 C152 C114 C146	31829030 31829080 31829300 31829470	* * *	4 4 4	" "	30PF 47PF 5PF	SL SL	D207	21019410	"	"	"	1S1941

		THERMIST	OR								
RS201	29090001	SDT-25	50								
		CRYSTAL	FILTER	2					INDUCTOR		
XF201	71000020	XF10A			#	210027	L201	53020032	Micro Inductor	· FL-4H	3.9µH
							L202	53020006	"	"	6.8µH
							L203	53010004	*	FL-5H	220µH
		RESISTOR									
R251	40143560	Carbon	Film	1⁄4 W	VJ	56Ω					
R209,212,214,219,245	40143101	"	"	*	"	100Ω			TRANSFORMER		
R246,249		"	"	"	"		T201,202	54140740	R12-4074		# 220150
R226,229	40143721	"	"	*	"	270Ω	T203	54140730	R12-4073		# 220149
R218,231	40143471	"	"	"	"	470Ω					
R224	40143561	"	"	"	"	560Ω					
R202,235	40143681	"	*	"	"	680Ω					
R204,205,211,215,221	40143102	"	"	"	"	1ΚΩ					
R228,230,241,247			"	"	"						
R208,210,217,223,248	40143222.	*	"	"	"	2.2KΩ		FM	IF unit		
R227	40143272	"	"	"	"	2.7KΩ	Symbol Number	Parts Numb er	Descr	iption	
R201,203,213,234,250	Constant of the constant of the	"	"	"	"	3.3KΩ	PB-1463 C-3340	60414633	Printed Circui		
R225,239,240	40143392	*	"	"	"	3.9KΩ	0.0010	014633AZ		to a savet non	
R242	40143472	"	"	"	"	4.7KΩ			1 ob and com	ponento	
R206	40143682	"	"	"	"	6.8KΩ					
R236	40143103	"	"	"	"	10KΩ					
R233	40143153	"	"	"	"	15ΚΩ			IC, FET & TRANS	SISTOP	
R220	40143223	"	"	"	"	22KΩ	Q302	25000111	IC	JULIA	#A703HC
R207	40143223	"	"	"	"	27KΩ	Q308	25000099	//		TA7061AP
R237	40143213	*	"	"	"	39KΩ	Q303	22800195	FET		14 - 222m
R232,238	40143333		"	"	"	47KΩ	Q301,304~307,309~	22303724	Transistor		2SK19GR
R216,244	40143473	"	"	"	"	47 K42 100KΩ	Q311	22303724	Transistor		2SC372Y
R222	40143104	"	"	*	"	470KΩ	4311				
R252	40143474	4	4	"	TJ	470K12 1KΩ	7				
11252	41143102		1		15	11/22					
									DIODE		
							Daga saa	01001000	DIODE		10100531
							D303~306	21001880	Germanium Di		1S188FM
							D301,302,307~310	21015550	Silicon	"	1S1555
UDoot	10000100	POTENTION									
VR201	49906102	EVL-SO			_	1ΚΩΒ					
VR202,203	49906502	EVL-SC	DAA-001	B 53		5ΚΩΒ			THERMISTOR		
							RS301	29090001	SDT-250		
		1					RS301	29090001	SDT-250		
		1					RS301	29090001	SDT-250		
		CAPACITOR					RS301	29090001			
C215	31820100	Ceramic	c Disc	202023	122510-0	F NPO		29090001	CRYSTAL		
C214	31820200	Ceramic ″	c Disc	"	20 P F	r NPO	RS301 X301	29090001 71800061	CRYSTAL	10.245MH	z
C214 C216,247	31820200 31820101	Ceramic	c Disc	"	20 P F	0.000.000			CRYSTAL	10.245MH	z
C214 C216,247 C241,248	31820200 31820101 30820102	Ceramic * *	c Disc	"	20PH 100P	F NPO FNPO 001µF			CRYSTAL	10.245MH	z
C214 C216,247 C241,248 C201~204,210~213,	31820200 31820101	Ceramic %	c Disc	<i>"</i>	20PH 100P	F NPO FNPO			CRYSTAL	10.245MH	z
C214 C216,247 C241,248	31820200 31820101 30820102	Ceramic * *	c Disc	4 14 14	20PH 100P	F NPO FNPO 001µF			CRYSTAL		z
C214 C216,247 C241,248 C201~204,210~213,	31820200 31820101 30820102	Ceramic * *	c Disc	4 14 14	20PH 100P	F NPO FNPO 001µF			CRYSTAL HC-18/U	1	z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224,	31820200 31820101 30820102	Ceramic * *	c Disc	4 14 14	20PH 100P	F NPO FNPO 001µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER	1	z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240,	31820200 31820101 30820102	Ceramic * *	c Disc	4 14 14	20PH 100P 0.0	F NPO FNPO 001µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF-	1	z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244	31820200 31820101 30820102 30820103	Ceramic // // //	c Disc	*	20 PH 100 P 0.0	F NPO FNPO 001µF 01µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF-	1	z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218	31820200 31820101 30820102 30820103 30820473	Ceramic * * *	c Disc	* * *	20PF 100P 0.0 0.0	F NPO FNPO 001µF 01µF 047µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF-	1	z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233	31820200 31820101 30820102 30820103 30820473 30820473 36825682	Ceramic * * * * *	c Disc	* * * *	20 PH 100 P 0.0 0.0 0.0 0.0	F NPO FNPO 001µF 01µF' 047µF 0068µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF-	1	Z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233 C223,231,232	31820200 31820101 30820102 30820103 30820473 36825682 36825223	Ceramic % % Mylar %	c Disc * * *	* * * *	20 PF 100 P 0.0 0.0 0.0 0.0 0.0	F NPO FNPO 001µF 01µF 047µF 0068µF 02µF	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF-	1	Z
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233 C223,231,232 C222	31820200 31820101 30820102 30820103 30820473 36825682 36825223 36825104	Ceramic % % % % Mylar % % % % % % % % % % % % % % % % % % %	c Disc * * * *	* * * * * * * * * * * * * * * * * * *	20 PF 100 P 0.0 0.0 0.0 0.0 0.0 0.0	F NPO FNPO 001µF 001µF 0047µF 0068µF 0068µF 002µF 1µF 333µF.	X301	71800061	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF- 10.7MF-BR	2 C12	
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233 C223,231,232 C222 C235	31820200 31820101 30820102 30820103 30820473 36825682 36825223 36825104 36526334	Ceramic % % % % Mylar % Tantalu	c Disc * * * *	* * * * * * * * * * * * * * * * * * *	20PF 100P 0 0 0 0 0 0 1µ	F NPO FNPO 001μF 01μF 0047μF 0068μF 02μF 1μF 33μF. F	X301 CF302 CF303 R304,305,326	71800061 71800061 71200009 71200010 40143101	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF- 10.7MF-BR RESISTOR	1	100Ω
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233 C223,231,232 C222 C235 C229	31820200 31820101 30820102 30820103 30820473 36825682 36825223 36825104 36526334 34220105	Ceramic % % % % Mylar % Tantaluı Electro	c Disc * * * *	* * * * * * * * * * * * * * * * * * *	20PH 100P 0.4 0.4 0.4 0.4 0.4 0.4 0.4 0.4 0.4 0.4	F NPO FNPO 001μF 001μF 0047μF 0068μF 02μF 1μF 33μF. F 7μF	X301 CF302 CF303	71800061 71800061 71200009 71200010 40143101 40143221	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF- 10.7MF-BR RESISTOR Carbon Film	2 C12 ¼WVJ * *	100Ω 220Ω
C214 C216,247 C241,248 C201~204,210~213, C219,220,221,224, C226,227,236~240, C242,244 C205~209,217,218 C233 C223,231,232 C222 C235 C229 C230	31820200 31820102 30820103 30820103 30820473 36825682 36825223 36825104 36526334 34220105 34220475	Ceramic % % % % Mylar % Tantalu Electro %	c Disc * * * *	* * * * * * * * * * * * * * * * * * *	20PF 100P 0 0 0 0 0 0 1µ	F NPO FNPO 001µF 001µF 0047µF 0068µF 0068µF 02µF 1µF 33.µF. F 7µF uF	X301 CF302 CF303 R304,305,326 R325,327,337	71800061 71800061 71200009 71200010 40143101	CRYSTAL HC-18/U CERAMIC FILTER CFM455F/LF- 10.7MF-BR RESISTOR Carbon Film * *	2 C12 <sup>1</sup> /4WVJ	100Ω

R309	40143152	Carbon Film	1/4 W	VJ 1.5KΩ	r		IC. FET & TRAN	SISTOR		
R339,340	40143132	<i>* *</i>	14.17F	<ul> <li>2.2KΩ</li> </ul>	Q415	25000111	IC			AC14011B
R311,313,314,321,343	40143332			<ul> <li>3.3KΩ</li> </ul>	Q416,417	22800195	FET			SK19GR
R349~356	10110002			0.012-	Q412	22105641	Silicon Trans	istor	-	SA564A
R301,330,331,335,344	40143472	" "	"	4.7KΩ	Q404	22105041	5111con 114n5	15101		SA695
R322,338	40143472		"	<ul> <li>φ. 1 και</li> <li>φ. 5.6 κΩ<sup>1</sup></li> </ul>	Q404 Q406	22205290	"			SB529
R302	40143562	<i>" "</i>	"	<ul> <li>σ. 6K12</li> <li>φ 10KΩ</li> </ul>	Q401,402,407,408,414	22205290	"			2SC372Y
R315,316,345	40143103		"		Q409,410,413,418		"			2SC3721
and the second		··· ··	"			22303730 22307110	"			
R323,334,341	40143223	* *			Q403	22307110			_	2SC711 2SC735Y
R320,332	40143473			<ul> <li>47KΩ</li> <li>56KΩ</li> </ul>	Q411		"			
R348 R306,307,310	40143563	" "	"		Q405	22403590	"			2SD359
R306,307,310	40143104	* *	"	<ul><li>100KΩ</li></ul>						
							DIODE			
					D401~404,406	21015550	Silicon Diode		1	S1555
		*			Contraction of Street S					AV-5W
		CADACITOD			D405	29090013	Varistor		1	VI V-5 W
6910	01000050	CAPACITOR	FOILIT	FDECI						
C312	31829050	Ceramic Disc	50W V	5PFSL						
C306,307	31829330	" "	"	33PF SL						
C309,343	31829101	" "		100PFSL			RESISTOR	1 /		
C301	31829221	" "		220PFSL	R416	40143100	Carbon Film	1⁄4 W	_	10Ω
C333	31820400	" "		40PF CH	R414	40143220	* *	"	"	22Ω
C344	30820102	" "	"	0.001µF	R456	40143680	" "	"	"	68Ω
C302~305,308,313,	30820103	* *	"	0.01µF	R457	40143101	* *	"	"	100Ω
C315,316,319,336,					R420	40143121	" "	"	"	120Ω
C345~348					R403,417,449	40143221	" "	"	"	220Ω
C310,330,331,337,338	36825103	Mylar *	"	0.01µF	R425,454	40143471	" "	"	"	470Ω
C341					R406,407,428,430,434	40143102	* *	"	"	1ΚΩ
C328,329	36825223	4 4	"	$0.02\mu$ F	R441					
C311,317,320~325	36825473	" "	1.	0.047µF	R412,413	40143152	" "	"	"	1.5KΩ
C339,340,349,350	36526105	Tantalum	25WV	1µF	R402,408,424,450,452,453	40143222	" "	"	"	2.2KΩ
C335	36824101	Styrol	50W V	100PF	R415	40143332	* *	"	"	3.3KΩ
C326,334	36824331	"	"	330PF	R401,440,443,445,446	40143472	" "	"	"	4.7KΩ
C327	36824102	"	"	1000PF	R448,455					
C332,342	34220475	Electrolytic	16WV	4.7µF	R429	40143562	* *	"	"	5.6KΩ
					R409	40143682	" "	"	"	6.8KΩ
					R404	40143822	* *	"	"	8.2KΩ
					R421,427,436,438,439	44143103	* *	"	"	10KΩ
					R444					
					R422,442	40143223	" "	"	"	22KΩ
		INDUCTOR			R447	40143333	* *	"	. "	33KΩ
L301~303,306~308	53020001	Micro Inductor	FL5H	1mH	R405,426	40143393		"	"	<b>39KΩ</b>
L305	53020002	"	"	2mH	R410	40143473	" "	"	"	47ΚΩ
L304	53010003	"	EL061	0 250µH	R435	40143563	* *	"	"	56KΩ
		4			R423	40143683	" "	"	"	68KΩ
					R411,437,451	40143104	" "	"	"	100KΩ
					R431,432	40143105	" "	"	"	1ΜΩ
		TRANSFORMER			R433	40143335	" "	"	"	3.3MΩ
T301,302	54140740	R12-4074		# 220150	R418,419	40124029	Wire Wound	1/2 W		0.22Ω
T303	54148614	R12-4861D		# 220182		10121020				
T304	54148615	R12-4861E		# 220182						
T305	55000278	7MC312162N		# 220183						
1 305	55000278	7MC312102N		# 220100						
							POTENTIOMETE	D		
TD201 200	01100000	Wasaniaa	ninel C		VR404	40006502	EVL-SOAA-(			5ΚΩΒ
TP301,302	91100008	Wrapping Tern	ninal C		VR404 VR403	49906502	-		-	10KΩB
						49906103	EVL-SOAA-(			
					VR402	49907053	EVL-VOAA-(			50KΩB
					VR405	49906503	EVL-SOAA-(			50KΩB
					VR401	49907504	EVL-VOAA-(	UB 55		500KΩB
		AMP unit								
Symbol Number	Parts Number		ription			•				
PB-1764	60417640		0							
	017640AZ	PCB with com	nononte							

		CAPACITOR			R502 505 515 507 504	401 49100	Carter	Film	1/10	VI	120
C438	31829151	CAPACITOR Ceramic Disc	c 50WV	150PFSL	R502,505,515,527,534 R546	40143102	Carbon	rılm	1⁄4 W	٧J	1ΚΩ
C404	31829131		0850	220PFSL	R511	40143122	"	"	"	"	1.2K
C404 C434	31829221			220FFSL 270PFSL	R532	40143122	*	"	"	"	2.2K
C409	33834331			330PFSL	R524	40143222 40143272		"	"	"	2.2K
C409 C427	30820102		" .	0.001µF	R507,517,529		"	"	"	"	2.7K
C427 C401	30820102		"	0.001µF	R547,553	40143332 40143392	"	"	"	"	3.3K
C401 C410,411	30820473	Mylar	"	0.047µF	R547,553 R510,535		"	"	"	"	3.9K
						40143472			: 24		
C423,436,437	36825103	*	"	0.01µF	R536,539	40143562	*	"	*	"	5.6K
C420	36825102	"	"	0.001µF	R540	40143682	*	"	"	"	6.8K
C431~433	36825223	"	"	0.02µF	R508	40143822	"	"	*	"	8.2K
C414,417	36825473	*	*	0.047µF	R522,525	40143103	"	"	"	"	10KΩ
C422.	36526334	Tantalum	35W V	0.33µF	R513	40143183	"	"	"	"	18KΩ
C425	36526105	"	"	1μF	R523,526	40143223	"	"	"	"	22KΩ
C424	36526225	"	"	2.2µF	R528	40143273		"	"	"	27KC
C403,406,415,419,428	34820105	Electrolytic	50W V	1µF	R501,509,518	40143333	"	"	"	"	33KC
C430				1.0	R516,519	40143683	"	"	"	"	68KC
C402,435	34220475	*	16W V	4.7µF	R548	40143104	"	"	"	"	100K
C416,418,421,426,429	34220106	"	. "	10µF			-				
C439	34120475	*	10W V	,47μF							
C405,407	34220107	*	16 W V	100µF							
C408,412	34220227.	"	"	220µF							
	/										
		·					POTENTION				
					VR507	49906102	EVL SC				1KΩI
					VR504	49906202	EVL SC				2KΩ]
		. Jahr and			VR501~503,506	49906502	EVL SC	DAA 00	B53		5KΩ]
	MIC	C AMP unit			VR505	49916301	SR29R				300Ω
Symbol Number	Parts Number		cription								
PB-1753	60417530	Printed Circ	uit Board								
	017530AZ	PCB with co	ompoņents								
							CAPACITOR	2			
					C544	31829040	Ceramic	e Disc	50W \	V 4PF	SL
					C551	31829100	"	"	"	10PF	SL
		IC. FET & TRA	NSISTOR		C556	31829220	"	"	"	22PF	SL
Q501	25000099	IC		TA7061AP	C520	31829151	"	"	"	150P	FSL
Q509	22800195	FET		2SK19GR	C510,511	31829271	"	"	"	270P	
Q510	22800194	*		2SK19Y	C526	31820030	"	"	"	3PF	
Q502,503	22310005	Silicon Tran	sistor	2SC1000GR		31820150	"	"	"		
Q504~508	22303724	*	*	2SC372Y	C542	31820200	"	"	"		
4004 000	22000124			2000121	C560	31820270	"	"	1 Co.	27PF	
					0000				~ ~	4111	VII
					C532~534 548				*		
Pres.					C532~534,548	31820300	"	"	"	30PF	с СН
		DIODE			C527,528,541	31820300 31820101	" "	" "	*	30PF 100P	CH FCH
DE07- 510	01010070	DIODE	D: 1	101002	C527,528,541 C540	31820300 31820101 31820151	* *	* * *		30PF 100P 150P	F CH FCH FCH
	21010070	Germanium		1S1007	C527,528,541 C540 C516,552	31820300 31820101 31820151 30820102	* * *	* * *	"	30PF 100P 150P 0.001	FCH FCH FCH
D503 ~506	21015550	Germanium Silicon	"	1S1555	C527,528,541 C540 C516,552 C529~531,535~539,	31820300 31820101 31820151	* *	* * *	"	30PF 100P 150P	FCH FCH FCH LµF
D503 ~506 D501	21015550 21090137	Germanium Silicon Varactor	" "	1S1555 FC63- 4	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549,	31820300 31820101 31820151 30820102	* * *	* * *	"	30PF 100P 150P 0.001	FCH FCH FCH
D503 ~506 D501	21015550	Germanium Silicon	"	1S1555	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555	31820300 31820101 31820151 30820102 30820103	* * *	" " " "	*	30PF 100P 150P 0.001 0.01/	F CH F CH F CH F CH IµF µF
D503 ~506 D501	21015550 21090137	Germanium Silicon Varactor	" "	1S1555 FC63- 4	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525	31820300 31820101 31820151 30820102 30820103 30820473	* * * *	11 14 14 14 14 14 14 14 14 14 14 14 14 1	* *	30PF 100P 150P 0.001 0.01/	Γ CH FCH FCH μF μF μF
D503 ~506 D501	21015550 21090137	Germanium Silicon Varactor	" "	1S1555 FC63- 4	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524	31820300 31820101 31820151 30820102 30820103 30820473 33824751	۵ ۵ ۵ Dipped	11 14 14 14 14 14 14 14 14 14 14 14 14 1	*	30PF 100P 150P 0.001 0.01/ 0.04/ 750P	F CH FCH FCH IµF µF 7µF F
D503 ~506 D501	21015550 21090137	Germanium Silicon Varactor Varistor	" "	1S1555 FC63- 4	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102	* * * * Dipped Mylar	11 14 14 14 14 14 14 14 14 14 14 14 14 1	* * *	30PF 100P 150P 0.001 0.01/ 0.047 750P 0.001	F CH FCH FCH μF μF μF F
D503 ~506 D501 D502	21015550 21090137 29090004	Germanium Silicon Varactor Varistor CRYSTAL	" "	1S1555 FC63- 4	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103	۵ ۵ ۵ Dipped	11 14 14 14 14 14 14 14 14 14 14 14 14 1	* * * *	30PF 100P 150P 0.001 0.01/ 0.047 750P 0.001 0.01/	F CH FCH FCH μF μF F μF μF
D503 ~506 D501 D502 X501	21015550 21090137	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM	* * 10.7000	1S1555 FC63- 4 MV103 # 210049-1	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102	* * * * Dipped Mylar	11 14 14 14 14 14 14 14 14 14 14 14 14 1	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01/ 0.04/ 750P 0.001 0.01/ 0.02/	F CH FCH FCH μF μF τ F μF F μF 2μF
D503 ~506 D501 D502 X501 X501 X502	21015550 21090137 29090004 71800062 71800065	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM * CW	* * 10.7000 10.6993	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103	* * * * * * * Dipped Mylar *	" " " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01/ 0.047 750P 0.001 0.01/	F CH FCH FCH μF μF τ F μF F μF 2μF
D503 ~506 D501 D502 X501 X 502	21015550 21090137 29090004 71800062	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993 3 10.6985	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1 # 210051-2	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508 C509	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103 36825223	<pre>% % % % Dipped Mylar % % % % % % % % % % % % % % % % % % %</pre>	" " " " " " Mica	* * * * * *	30PF 100P 150P 0.001 0.01/ 0.04/ 750P 0.001 0.01/ 0.02/	F CH FCH FCH μF μF τ F μF F μF 2μF
D503 ~506 D501 D502 X501 X501 X502 X503	21015550 21090137 29090004 71800062 71800065	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508 C509 C558	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103 36825223 368252474	<pre>% % % % Dipped Mylar % Tantaluu </pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.014 750P 0.002 0.014 0.022 V 0.47	F CH FCH FCH μF μF τ F μF F μF 2μF
D503 ~506 D501 D502 X501 X501 X502 X503	21015550 21090137 29090004 71800062 71800065 71800064	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993 3 10.6985	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1 # 210051-2	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508 C509 C558 C523	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105	<pre> % % % % Dipped Mylar % Tantalu % % % % % % % % % % % % % % % % % % %</pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01μ 0.047 750P 0.001 0.01μ 0.022 V 0.47μ 1μF	F CH FCH FCH μF μF τ F μF F μF 2μF
D503 ~506 D501 D502 X501 X501 X502 X503	21015550 21090137 29090004 71800062 71800065 71800064	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993 3 10.6985	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1 # 210051-2	C527,528,541 C540 C516,552 C529~531,535~539, C543,545~547,549, C550,553,555 C525 C524 C517 C508 C509 C558 C523 C523 C501,512,515,518,521 C557	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220105	<pre> % % % % Dipped Mylar % Tantalu % % % % % % % % % % % % % % % % % % %</pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.014 750P 0.001 0.014 0.022 V 0.474 1µF V 1µF	CH FCH FCH μF μF F μF μF μF μF μF μF μF
D503 ~506 D501 D502 X501 X501 X502 X503	21015550 21090137 29090004 71800062 71800065 71800064	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993 3 10.6985	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1 # 210051-2	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \sim 531, 535 \sim 539, \\ C543, 545 \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C509 \\ C557 \\ C502, 504 \sim 507, 514, \\ \end{array}$	31820300 31820101 31820151 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105	% % % % Ø	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01μ 0.047 750P 0.001 0.01μ 0.022 V 0.47μ 1μF	CH FCH FCH μF μF F μF μF μF μF μF μF μF
D503 ~506 D501 D502 X501 X501 X502 X503	21015550 21090137 29090004 71800062 71800065 71800064	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB	* * 10.7000 10.6993 3 10.6985	1S1555 FC63- 4 MV103 # 210049-1 # 210051-1 # 210051-2	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \\ \sim 531, 535 \\ \sim 539, \\ C543, 545 \\ \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C501, 512, 515, 518, 521 \\ C557 \\ C502, 504 \\ \sim 507, 514, \\ C519, 522 \\ \end{array}$	31820300 31820101 31820102 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220106	* * * * * Dipped Mylar * Tantalum * Electrol *	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.014 750P 0.001 0.014 750P 0.001 0.014 1μF 10μF 10μF	CH FCH FCH μF FCH μF F μF μF μF μF
D503 ~506 D501 D502 X501 X501 X502 X503 X504	21015550 21090137 29090004 71800062 71800065 71800064 71800063	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB & LSB RESISTOR	* * 10.7000 10.6993 3 10.6985 3 10.7015	1S1555 FC63- 4 MV103 #210049-1 #210051-1 #210051-2 #210051-3	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \sim 531, 535 \sim 539, \\ C543, 545 \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C501, 512, 515, 518, 521 \\ C557 \\ C502, 504 \sim 507, 514, \\ C519, 522 \\ C513 \\ \end{array}$	31820300 31820101 31820101 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220106 34220106	<pre>% % % % % Dipped % Dipped % Tantalu % Electrol % % % % % % % % % % % % % % % % % % %</pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01/ 0.04/ 750P 0.001 0.01/ 0.022 V 0.47/ μF 10μF 22μF	CH FCH μF μF μF Γ μF μF μF μF μF
D503 ~506 D501 D502 X501 X501 X502 X503 X504 R504,512,521,530,531	21015550 21090137 29090004 71800062 71800065 71800064 71800063	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB & LSB	* * 10.7000 10.6993 3 10.6985 3 10.7015	1S1555 FC63- 4 MV103 #210049-1 #210051-1 #210051-2 #210051-3	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \\ \sim 531, 535 \\ \sim 539, \\ C543, 545 \\ \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C509, 512, 515, 518, 521 \\ C557 \\ C502, 504 \\ \sim 507, 514, \\ C519, 522 \\ \end{array}$	31820300 31820101 31820102 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220106	* * * * * Dipped Mylar * Tantalum * Electrol *	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.014 750P 0.001 0.014 750P 0.001 0.014 1μF 10μF 10μF	CH FCH μF μF μF Γ μF μF μF μF μF
D507~510 D503 ~506 D501 D502 X501 X502 X503 X504 R504,512,521,530,531 R533,538,543~545, R549,550,551	21015550 21090137 29090004 71800062 71800065 71800064 71800063	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB & LSB RESISTOR	* * 10.7000 10.6993 3 10.6985 3 10.7015	1S1555 FC63- 4 MV103 #210049-1 #210051-1 #210051-2 #210051-3	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \sim 531, 535 \sim 539, \\ C543, 545 \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C501, 512, 515, 518, 521 \\ C557 \\ C502, 504 \sim 507, 514, \\ C519, 522 \\ C513 \\ \end{array}$	31820300 31820101 31820101 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220106 34220106	<pre>% % % % % Dipped % Dipped % Tantalu % Electrol % % % % % % % % % % % % % % % % % % %</pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01/ 0.04/ 750P 0.001 0.01/ 0.022 V 0.47/ μF 10μF 22μF	CH FCH FCH μF μF F μF μF μF μF μF
D503 ~506 D501 D502 X501 X501 X502 X503 X504 R504,512,521,530,531	21015550 21090137 29090004 71800062 71800065 71800064 71800063	Germanium Silicon Varactor Varistor CRYSTAL HC18/U FM & CW & USB & LSB RESISTOR	* * 10.7000 10.6993 3 10.6985 3 10.7015	1S1555 FC63- 4 MV103 #210049-1 #210051-1 #210051-2 #210051-3	$\begin{array}{c} C527, 528, 541 \\ C540 \\ C516, 552 \\ C529 \sim 531, 535 \sim 539, \\ C543, 545 \sim 547, 549, \\ C550, 553, 555 \\ C525 \\ C525 \\ C524 \\ C517 \\ C508 \\ C509 \\ C558 \\ C523 \\ C501, 512, 515, 518, 521 \\ C557 \\ C502, 504 \sim 507, 514, \\ C519, 522 \\ C513 \\ \end{array}$	31820300 31820101 31820102 30820102 30820103 30820473 33824751 36825102 36825103 36825223 36526474 36526105 34220106 34220106	<pre>% % % % % Dipped % Dipped % Tantalu % Electrol % % % % % % % % % % % % % % % % % % %</pre>	" " " " " Mica	* * * * * * * * * * * * * * * * * * *	30PF 100P 150P 0.001 0.01/ 0.04/ 750P 0.001 0.01/ 0.022 V 0.47/ μF 10μF 22μF	CH FCH FCH μF μF F μF μF μF μF μF

		TRIMMER CAPACITOR								
TC501~504	39000007	ECV-1ZW 20×40	20PF							
10001 001	0000001		2011							
									20.000	
	-	INDUCTOR				POTENTIOM	ETER			
L501	55003256	VXO Coil	# 220319	VR601	49906102	EVE-SOA		3	1	1ΚΩΒ
L502~504,506	53020001	Micro Inductor FL5		VR602	49916473	SR29R				47KΩ
L507	53010003	* *	250µH	11002	10010110					4/1042
1.501	33010003		250411							
	-									
				1		CAPACITOR				
		TRANSFORMER		C613,619,623,631	31829100	Ceramic	Disc	50W V	10PF	SI.
T501	54140740	R12-4074	# 220150	C601	31829400	/	<i>"</i>	*	40PF	
T502,503	54140730	R12-4073	# 220130	C626	31829470	"	"	"	47PF	
1502,505	54140750	112 4015	# 220145	C614,615	31820010	"	"	"	133	CH
				C616~618,622	31820050	"	"	"		CH
				C611,612	31820100	"	"	"	10PF	
	1			C606,607	31820200	4	"	"	20PF	
				C603~605,620,621,	30820102	"	4	*	0.001/	100.00
and the second se	EVO	CITER unit		C624,639~645	00020102			2	0.001	
Symbol Number	Parts Number	Description		C602,608~610,625	30820103	"	*	*	0.01µ	F
PB-1762	Number 60417620	Printed Circuit Board		C602,608~610,625 C627~630,637	00020103		5 pr.	1	0.01µ	
1.D-1102	017620AZ			C627~630,637	36825473	Mylar	"		0.047	μF
	017620AZ	rob with components		C632 C633,636,638	36825473	Electolyt		7 16WV	14	μ.Γ.
				C635	34220106	Electoryt	ic	16w v	10μF	
						*			1.00	-
				C634	34220336	~		"	33µF	
0001 000	00000105	FET & TRANSISTOR	ACK10CD							
Q601,602	22800195	FET	2SK19GR							
Q603	22307842	Silicon Transistor	2SC784R							
Q604,605	22320530	* *	2SC2053							
Q606	22307300	* *	2SC730	2						
Q607,610	22303730	" "	2SC373			TRIMMER C				
Q608	22303724	* *	2SC372Y	TC601~606	39000006	ECV-1ZV		_		10PF
Q609	22307354	" "	2SC735Y	TC607,608	39000011	ECV-1ZV				20PF
				TC609	3900002	ECV-1ZV	V 20×32			20PF
	-	DIODE								
D601~605	21022090	Varactor Diode	1S2209			INDUCTOR				
D606~608	21015550	Silicon *	1S1555	L601,603	55003257				- A1122	20320
				L602	55003258					20321
				L604	55003259					20322
				L606,608	55003260	1			19.13	20323
		RESISTOR		L610	55033264					20315
R617,622	40143100	Carbon Film <sup>1</sup> / <sub>4</sub> W	VJ 10Ω	L605	55003254					20310
Ř623,626	40143560	* * *	* 56Ω	L607	55003262					20324
R613,618,637,639	40143101	* * *	* 100Ω	L609	55003263			4 	#2	20311
R612	40143221	* * *	* 220Ω							
R630	40143471	" " "	* 470Ω							
R615,620	40143561	4 4 4	* 560Ω							
R635	40143821	<i>" " "</i>	» 820Ω			TRANSFORM	IER			
R633,641	40143102	* * *	» 1KΩ	T601	54140730	R12-4073			#2	20149
R625	40143122	* * *	* 1.2KΩ	T602	55003265				#2	20325
R634,636,640	40143222	* * *	<ul><li>2.2KΩ</li></ul>							
R608,610	40143332		* 3.3KΩ		-					
R616,621,638	40143472	<i>h h h</i>	# 4.7KΩ							
R628	40143562	* * *	* 5.6KΩ		BOOS	STER unit				
R632	40143103	* * *	* 10KΩ	Symbol Number	Parts Number		Descrip	otion		
11052	40143153	* * *	* 15KΩ	PB-1744	60417440				A	
R611,631	10110100						"	"	В	
	40143273	* * *		PB-1745	60417450		"	"	D	
R611,631		0 0 0 0 0 0	<ul> <li>27KΩ</li> <li>47KΩ</li> </ul>	PB-1745	60417450 017440AZ				D	
R611,631 R629 R601,602	40143273 40143473		Contraction of the second s	PB-1745					P	
R611,631 R629	40143273	* * *		PB-1745					D.	

		TRANSISTOR			INDUCTOR	
Q701	22390005	Transistor MRF212	L701	55003266		#220326
Q702	22390003	* 2N5591	L702~704	55003267		# 220328
			L713	55003273		#220327
			L705,707	55003268		# 220330
			L706,708	55003269		#220329
		DIODE	L709,710	55003270		# 220331
D711~713	21001880	Germanium Diode 1S188FM	L711	55003272		# 220334
D702,703	21090011	Silicon / 10D1	L712	55003271		# 220333
D704~710,714,715	21015550	* * 1S1555	L714	53020014	Micro Inductor FL4H	1.8µH
D701	21090143	Zener / 1N4732				
					TRANSFORMER	
		RESISTOR	T701	55003274		# 220335A
R708	40143222	Carbon Film ¼W VJ 2.2KΩ				
R709	40143105	» « » « 1MΩ				6
R701,702	42124100	Composition ½W GK10Ω		-		
R704	42124470	* * * * 47Ω			RELAY	
R703	42124560	» » » » 56Ω	RL701	70000031	BR-221D012	DC12V
R710	43304390	Metalic Film 3W 39Ω		1000001		DOIDT
			1001		CONNECTOR	00.000
1			J701	68000007		SO-239
			J702	67090001		SI-8501
		POTENTIOMETER				
V R701	49906501	EVL-SOAA-00B52 500ΩB				
VR702~704	49906103	EVL-SOAA-00B14 10KΩE	3			
			Symbol Number	Parts Number	CAL unit Description	
		CAPACITOR	PB-1805	60418050	Printed Circuit Board	
C733	31829059	Ceramic Disc 50WV 0.5PFSL	1.0.1000	018050AZ	PCB with components	
C725	31829010	* * * 1PF SL		010000111	Top and components	
C726	31829020	* * * 2PF SL				
C727	31829030	* * * 3PF SL	1.			
C718	31829090	* * * 9PF SL			TRANSISTOR	
C701	31829100	* * * 10PF SL	Q801,802	22303724	Silicon Transistor	2SC372Y
C719,721,724	31829100	* * * 15PF SL	Q803	22303724		2SC3721 2SC784R
C708	31829130	* * * 1311 SL	4003	22307842	, ,	250704N
C708	31829180	* * * 20PF SL				
Ser 110 per	31829200					
		* * * 33PF SL			DIODE	
C710	31829101	* * * 100PFSL	D017	01001000	DIODE	10100514
C710 C709	31829101 31827100	* * * 100PFSL	D817	21001880	DIODE Germanium Diode	1S188FM
C703,707,713,714,728	31829101 31827100	* * * 100PFSL	D801~812	21015550	Germanium Diode	1S1555
C710 C709 C703,707,713,714,728 C730,731,734~738,	31829101 31827100	* * * 100PFSL	D801~812 D813	21015550 21090108	Germanium Diode * Varactor *	1S1555 1SV50
C710 C709 C703,707,713,714,728 C730,731,734~738, C745	31829101 31827100 30820102	* * * 100PFSL * * * 10PF UJ * * * 0.001µF	D801~812	21015550	Germanium Diode	1S1555
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715	31829101 31827100 30820102 30820103	* * * 100PFSL * * * 10PF UJ * * * 0.001µF	D801~812 D813	21015550 21090108	Germanium Diode * Varactor *	1S1555 1SV50
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729	31829101 31827100 30820102 30820103 36825473	* * * 100PFSL * * * 10PF UJ * * * 0.001µF * * 0.01µF Mylar * 0.047µF	D801~812 D813	21015550 21090108	Germanium Diode * Varactor *	1S1555 1SV50
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747	31829101 31827100 30820102 30820103 368225473 36526104	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF	D801~812 D813	21015550 21090108	Germanium Diode  Varactor  v v	1S1555 1SV50
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816	21015550 21090108 21022090	Germanium Diode / Varactor / / / / CRYSTAL	1S1555 1SV50 1S2209
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747	31829101 31827100 30820102 30820103 368225473 36526104	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF	D801~812 D813 D814~816 X801	21015550 21090108 21022090 	Germanium Diode // Varactor // // // CRYSTAL HC-18/U 13.9MHz	1S1555 1SV50 1S2209 #210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816 X801 X802	21015550 21090108 21022090 71800100 71800100	Germanium Diode * Varactor * * CRYSTAL HC-18/U 13.9MHz * 14.0111	1S1555 1SV50 1S2209 # 210052- # 210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816 X801 X802 X803	21015550 21090108 21022090 71800100 71800100 71800101 71800102	Germanium         Diode           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         13.9MHz           %         14.0111           %         14.1222	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816 X801 X801 X802 X803 X803 X804	21015550 21090108 21022090 71800100 71800101 71800102 71800103	Germanium         Diode           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         14.0111           %         14.1222           %         14.2333	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816 X801 X801 X802 X803 X804 X805	21015550 21090108 21022090 71800100 71800101 71800102 71800103 71500104	Germanium         Diode           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         13.9MHz           %         14.0111           %         14.1222           %         14.2333           HC-25/U         13.8333	1S1555 1SV50 1S2209 #210052- #210052- #210052- #210052- #210052- #210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*     *     100PFSL       *     *     10PF UJ       *     *     0.001μF       *     *     0.01μF       Mylar     *     0.047μF       Tantalum     35WV 0.1μF       Fçed Thru     50WV 0.001μF	D801~812 D813 D814~816 X801 X801 X802 X803 X803 X804	21015550 21090108 21022090 71800100 71800101 71800102 71800103 71500104 71500176	Germanium         Diode           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         14.0111           %         14.1222           %         14.2333	1S1555 1SV50 1S2209 #210052- #210052- #210052- #210052- #210052- #210052-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749 C704,705,711,716	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.01μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed       .10PF         Electrolytic       16WV 10μF	D801~812 D813 D814~816 X801 X801 X802 X803 X804 X805	21015550 21090108 21022090 71800100 71800101 71800102 71800103 71500104	Germanium         Diode           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         %           %         13.9MHz           %         14.0111           %         14.1222           %         14.2333           HC-25/U         13.8333	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210052- # 210053- # 210053-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749 C704,705,711,716	31829101 31827100 30820102 30820103 36825473 36526104 32821102	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.01μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed Thru       50WV 0.001μF         Electrolytic       16WV 10μF	D801~812 D813 D814~816 X801 X802 X803 X804 X805 X806	21015550 21090108 21022090 71800100 71800101 71800102 71800103 71500104 71500176	Germanium         Diode           *         *           Varactor         *           *         *           *         *           CRYSTAL         *           HC-18/U         13.9MHz           *         14.0111           *         14.2333           HC-25/U         13.8333           HC-25/U         13.9444	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210053- # 210053- # 210053-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749 C704,705,711,716 TC701	31829101 31827100 30820102 30820103 36825473 36526104 32821102 34220106	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.01μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed       .10PF         Electrolytic       16WV 10μF	D801~812 D813 D814~816 X801 X802 X803 X804 X805 X806 X806 X806	21015550 21090108 21022090 71800100 71800100 71800101 71800103 71500104 71500176 71500186	Germanium         Diode           *         *           Varactor         *           *         *           *         *           *         *           CRYSTAL         *           HC-18/U         13.9MHz           *         14.0111           *         14.2333           HC-25/U         13.8333           HC-25/U         13.9444           *         14.0555	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210053- # 210053- # 210053- # 210053-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749	31829101 31827100 30820102 30820103 36825473 36526104 32821102 34220106 34220106 34220106	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.001μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed       Thru         50WV 0.001μF         Electrolytic       16WV 10μF         TRIMMER CAPACITOR         ECV=1ZW       10× 44	D801~812 D813 D814~816 X801 X802 X803 X804 X805 X806 X806 X806 X808	21015550 21090108 21022090 71800100 71800100 71800101 71800102 71800103 71500104 71500104 71500186 71500187	Germanium         Diode           *         *           Varactor         *           *         *           *         *           *         *           CRYSTAL         *           HC-18/U         13.9MHz           *         14.0111           *         14.1222           *         14.2333           HC-25/U         13.8333           HC-25/U         13.9444           *         14.0555           *         14.3000	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210053- # 210053- # 210053- # 210053- # 210053-
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749 C704,705,711,716 TC701	31829101 31827100 30820102 30820103 36825473 36526104 32821102 34220106 34220106 34220106	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.001μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed       Thru         50WV 0.001μF         Electrolytic       16WV 10μF         TRIMMER CAPACITOR         ECV=1ZW       10× 44	D801~812 D813 D814~816 X801 X802 X803 X804 X805 X806 X806 X806 X808 X809	21015550 21090108 21022090 71800100 71800100 71800101 71800102 71800103 71500104 71500176 71500186 71500187 	Germanium         Diode           *         *           Varactor         *           *         *           *         *           CRYSTAL         *           HC-18/U         13.9MHz           *         14.0111           *         14.1222           *         14.2333           HC-25/U         13.8333           HC-25/U         13.9444           *         14.0555           *         14.3000           *         Option	1S1555 1SV50
C710 C709 C703,707,713,714,728 C730,731,734~738, C745 C706,712,715 C729 C732,747 C739~744,746,749 C704,705,711,716 TC701	31829101 31827100 30820102 30820103 36825473 36526104 32821102 34220106 34220106 34220106	*       *       100PF SL         *       *       10PF UJ         *       *       0.001μF         *       *       0.001μF         Mylar       *       0.047μF         Tantalum       35WV 0.1μF         Feed       Thru         50WV 0.001μF         Electrolytic       16WV 10μF         TRIMMER CAPACITOR         ECV=1ZW       10× 44	D801~812 D813 D814~816 X801 X802 X803 X804 X805 X806 X806 X806 X808 X808 X809 X810	21015550 21090108 21022090 71800100 71800100 71800101 71800102 71800103 71500104 71500176 71500186 71500187 	Germanium         Diode           *         *           Varactor         *           *         *           *         *           CRYSTAL	1S1555 1SV50 1S2209 # 210052- # 210052- # 210052- # 210053- # 210053- # 210053- # 210053- # 210053- # 210053-

XS801,802	60000000	CRYSTAL S		1.11.000			Symbol News		X unit	D	dia dia		
X S801,802	6900006	S-14-12	P				Symbol Number	Parts Number	100 C 10		ription		
							PB-1750	60417500		0.00000	it Board	S	
								017500AZ	PCB w	ith con	nponents	ę.,	
D010 000 000 001	40142101	RESISTOR	P:1	1/11		1000							
R819,823,829,831 R828	40143101	Carbon		1⁄4 W	VJ	100Ω							
R822	40143221	"	"	"	"	220Ω	0001 000	00000000	TRANSIST		• and the baseline		
	40143561	"	"	"	"	560Ω	Q901,902	22303724	Silicon	n Trans	istor	25	SC372Y
R818a	40143102	"	"	"	"	1KΩ							
R801~812	40143152	*	"	"		1.5KΩ							
R813,827	40143222	*	"	"	"	2.2KΩ						_	
R817,821	40143472	"	"	"	"	4.7KΩ	Daat att		DIODE				
R816,826	40143103	*	"	"	"	10KΩ	D901~911	21015550	Silicor	n Diode		15	51555
R820	40143223	*	"	"	*	22KΩ							
R814,815	40143473	*	"	"	"	47KΩ							
R824,825,830	40143104	"	"	"	"	100KΩ							
									CRYSTAL	2762 2407 N			
							X901~905	-	HC-25/	U Opti-	on	#	210055
		CADACITE										_	
C000	91000050	CAPACITOR		FOILT					001071	000		_	
C839	31829059	Ceramic			0.5PF	1.012124	VS001	60000000	CRYSTAL		- 1		D
C844,852 C838,841	31829030	*	*	"	3PF 7PF	SL	XS901	69000006	HC-25	0		12	P
C838,841 C847	31829070 31829080	*	"	"	8PF	SL							
C837,840		*				SL							
2	31829150	*	"	"	15PF	SL	· · · · · · · · · · · · · · · · · · ·						
C842	31829180	*	"	*	18PF	SL	D005 000 000		RESISTOR		1 /		
C849	31829200	*	*	"	20PF	SL	R905,908,909	40143101	Carbon		1⁄4W	VJ	100Ω
C832	31829390	*	"	"	39PF	SL	R904	40143221	"	"	"	"	220Ω
C802~812	31827200	"	"	"	20PF	UJ	R901	40143152	"	"	"	"	1.5KΩ
C801,833	31827330	*	"	"	33PF	UJ	R902,907,910	40143562	"	"	"	"	5.6KΩ
C828	31827560	"	"	"	56PF	UJ	R906	40143822	"	"	"	"	8.2KC
C830	31827221	*	"	"	220PF	0.50365	R903	40143223	"	"	"	"	22KΩ
C850	30820102	*	"	"	0.001/								
C813~827,831,834~836	30820103	"	"	"	0.01µ	F							
C843,845,846,848	00005100	01:		0511/1	10.01								
C851	30325103	Chip		25 W V	/ 0.01µ	F							
									CARACITO	_			
							C000		CAPACITO		FOILT		<b>P QU</b>
							C930	31820080		c Disc			F CH
							C931	31820200	"	"			F CH
· · ·		TRUMER		TOD			C917~927	31820300	*	"	"		F CH
TC:000 010	20000007	TRIMMER O			0	0000	C929	31820101	*	"			PFCH
TC802~812	39000007	ECV-1Z	w	20×4		20PF	C928	31820201	*	"	"		PFCH
TC813,814	39000011	*		20×5		20PF	C932,933	31829201	"	"	"		PFSL
TC815	39000010	"		10×5	3	10PF	C901~916	30820103	"	"	"	0.01	μF
1 901	E4150000	INDUCTOR	NV.		# 64	00010							
L801	54150999	R12-5099	X		# 22	20313			TDANS	0.55		_	
							TC001 011	000000000	TRIMMER			0	DE
				_			TC901~911	39000007	ECV-1	ZW	$20 \times 4$	0 20	PF
		TOMOTOT	155	_									
T001 000		TRANSFORM		-	11.5								
T801,802	54147970	R12-4797				20110					_		
T803	54141020	R12-4102	2		# 22	20111			INDUCTOR				
			_	_			L901~911	53020001	Micro		r FL5H		nH
							L912	53010003		"			0μH
				12			L913	53020012		"	FL4H	H 1.	2µ H
TP801,802	91100008	Wrappin	g Termi	inal C									
the second s													

		_L unit					C1007	31820120	Cerami	c Disc	50W V	12PF CH
Symbol Number	Parts Number	De	script	on			C1037, 1044, 1046, 1047	31829470	"	"	"	47PF SL
		Printed	Circuit	Board	d		C1035	31829680	"	"	"	68PF SL
PB-1747	60417470	PD	boar	ł			C1032~1034	31829820	"	"	"	82PF SL
PB-1748	60417480	PLI	_ boar	d			C1029	31829101	"	"	"	100PFSL
PB-1830A	60418301	VCC	) boar	ł			C1057	31829221	"	"	"	220PFSL
	017480AZ	PLL un	it with	compo	nents		C1045	31829271	"	"	"	270PFSL
			94				C1056	31827070	"	"		7PF UJ
							C1008,1011~1014,	30820102	"	"		0.001µF
							C1017,1019,1020,					01002/-1
		IC, FET &	TRANS	ISTOR	2		C1024~1026,1031,					
Q1008	25000164	IC				PC78L05	C1048,1054		lin			
Q1009	25000135	"		#PC	100	'MC4044	C1030,1036,1038,1052	30820103	• *	"	"	0.01µF
Q1014	25000130	"		<i>µ</i>	201 - 115 - TAN	N75450B	C1053,1055	00020100				0.01/1
Q1001	22800196	FET		1		K19BL	C1042,1043	36526224	Tantalu	m	25WV	0.22µF
Q1002,1004	23800401	*				K40M	C1042,1045	36526334	1 antart			0.22μ F
Q1006,1007,1011	22303724	Silicon	Francia	tor		C372Y	C1040	36326685	Noise	imitan	20W V	
Q1010	22303724	311icon 4	/ 1 / 1 / 1 / 1	stor		C372 1	C1041 C1049~1051	32821102			and the second second	V 0.001μF
Q1003,1005	22303730	*	*			C784R	C1049~1051 C1010,1039	34220106			and the second	Control of the state of the sta
Q1005,1005	22307042				20	07041	01010,1039	54220100	Electro	lytic	16W V	10µ F
		IC SOCKET										
QS1001	68140008	116-14-3	80-114									
									TRIMMER	CAPAC	CITOR	
							TC1001	39000069	TZ01Y(	070A		7PF
							TC1002	39000010	ECV-12	ZW	10×53	10PF
		DIODE										
D1004~1008	21015550	Silicon	diode		15	1555						
D1001,1002	21022080	Varactor	• "		15	2208						
D1003	21022090	"	"		15	2209			INDUCTOR			
						_	L1002	55003275				# 220359 A
							L1004,1005	55003120	RFC			# 220206
							L1003	53020031	Micro	Inducto	r FL-4H	0.68µF
		RESISTOR					L1006,1007	53020005	"	"	"	3.3µH
R1003,1004,1008,1011	40143101	Carbon	Film	1⁄4W	VJ	100Ω	L1001	53020018	"	"	"	10µ H
R1013,1014,1018,1019							L1008	53020026	"	"	FL-5H	47µH
R1024,1030,1033							L1009	53020017	"	"	FL-4H	1.5µH
R1023,1028,1035,1041	40143102	"	"	"	"	1ΚΩ	L1010	53020027	"	"	100 C 100	270µH
R1045						00010	10000000				12 01	510/11
R1036	40143152	"	"	"	"	1.5KΩ						
R1032,1038,1039	40143222	"	"	"	"	2.2KΩ						
R1025	40143272	"	"	"	"	2.7KΩ			TRANSFOR	MED		
R1029	40143272	"	"	4	"	3.3KΩ	T1001	54141029	.R12-41			# 990111
R1012,1034,1040,1047	40143332	*	"	"	"	4.7KΩ	1001	34141029	• 112-41	52		#220111
R1012,1034,1040,1047 R1021,1027	40143472	*	*	. "	"	4.7Km 10KΩ						
R1021,1027	40143103	"	*	"	"	22KΩ						
R1010 R1022,1026	40143223	"	*	"	"	39KΩ		91100008	W	ng 4	ainal C	
R1022,1026	40143393 40143563	"	"	"	"	56KΩ		91100008	Wrappi	ng tern	inal C	
R1002 R1001,1005~1007,	40143563	"	"	"	"						1.000	
Sectores (CA) and a sector (CA) and a sector	40145104	"		"		100ΚΩ		91001102	Seal te	rminal	A102	
R1015~1017,1031,												
R1037,1043												
							Contraction of the second		BURST L			
							Symbol Number	Parts Number			ription	
							PB-1752	60417520			it Board	
		CAPACITOR	6					017520AZ	PCB w	ith com	ponents	
C1015	31820010	Ceramic		50W	V1PF	СН						
C1015 C1002	31820010	Ceramic	Disc //	50 W	2PF				·			
C1002 C1006	31820020	."			3PF				10 4 70.0			
			*	"			01101	0500011	IC & TRAI	VSISTO		
C1001,1016	31820050	"	*	"	5PF		Q1101	25000114	IC		MC140	
C1018	31820060	"	"	"	6PF		Q1102	25000155	"		MSM5	a na taon
C1003~1005	31820070	"	"	"	7PF 10PF	Second se	Q1103	22303724	Transis	stor	2SC37	
C1009, 1027, 1028	31820100	"	"	"	I O TOT	OTT	Q1104,1105	22310005	"		2SC10	and the second se

	DIODE					CONNECTOR	
21015550	Silicon Diode		1S1555	J1101	68060013	3022-06A	
	CRYSTAL					PLUG	
71500174		0Hz Tone	+ 210060-1	P1101	67040006		
	10-25/0 3.68	64MHz 0Hz Tone	+ 210000-1	1 1101	07040000	5021 04	
71500188							
	opti		1 210000 2				
			-				1
							_
69010012	HC-25/U	SD0105					
				PD-1751A			
					UTUTIT	r ob with components	
	RESISTOR						
40143101	Carbon Film	1⁄4 W V	VJ 100Ω				
40143471	<i>4</i> , <i>4</i> ,	"				IC & TRANSISTOR	
40143102	* *			Q1201	25000114	IC	MC14011B
	" "		0.0	Q1202	22303724	Transistor	2SC372Y
40143472	* *	4	4.7KΩ				
,1120 40143123							
5 40143123 5 40143473	" "	1000 C				DIOD5	
	* *			D1001- 1000	01015550		10100
	10 No.			D1201~1208	21015550	Silicon Diode	1S1555
41143105	" "	"	1J 1M11				
						RESISTOR	
				R1201, 1203, 1205	40143102	Carbon Film <sup>1</sup> / <sub>4</sub> W	1ΚΩ
				R1202	40143562	* * *	5.6KΩ
	POTENTIOM ETER	!		R1204	40143473	" " "	47ΚΩ
49907205	EVL-VOAA00F	26	$2M\Omega B$				
49907103	* *	14	10KΩB				
49906103		14	10ΚΩΒ				
	CARACITOR			C1201~1210	20820102		0.001µF
21820470		50WV	A7PE SI	An Alexandre Constants	Construction of the control	Checker and the state of the state of the state of the	etresses and the
				01211	30320334		0.3341
	" "	"	THE ALL OF THE PLANE				
	Mylar	"					
	*	"	Sector and the sector of the s				
36825103	"	"	0.01µF				
and the second sec	Tantalum	35W V	0.47µF			POTENTIOMETER	
		1000	1µF	VR1210	49906202	EVL-SOAA-B23	2ΚΩΒ
34220105	Electrolytic	16W V	1/41	VRIZIO	40000000		and the second se
	Electrolytic %	16W V	10µ F	VR1210 VR1201~1209	49906503	* * B54	50KΩB
34220105						* * B54	50KΩB
34220105 34220106	*	"	10µ F			* * B54	50KΩB
34220105 34220106 34220226	*	*	10µ F 22µ F			* * B54	50ΚΩΒ
34220105 34220106 34220226	*	*	10µ F 22µ F		49906503		50ΚΩΒ
34220105 34220106 34220226	*	*	10µ F 22µ F		49906503	* * B54 FO unit Description	50ΚΩΒ
34220105 34220106 34220226	*	*	10µ F 22µ F	VR1201~1209	49906503	F0 unit	50ΚΩΒ
34220105 34220106 34220226	*	*	10µ F 22µ F	VR1201~1209	49906503	FO unit Description	50ΚΩΒ
34220105 34220106 34220226	* * *	*	10µ F 22µ F	VR1201~1209	49906503	FO unit Description Printed Circuit Board	50ΚΩΒ
34220105 34220106 34220226 34220476	* * *	*	10µ F 22µ F	VR1201~1209	49906503	FO unit Description Printed Circuit Board	50ΚΩΒ
34220105 34220106 34220226 34220476	* * *	*	10µ F 22µ F	VR1201~1209	49906503	FO unit Description Printed Circuit Board	50ΚΩΒ
34220105 34220106 34220226 34220476	* * *	<i>*</i> <i>*</i>	10µ F 22µ F	VR1201~1209	49906503	FO unit Description Printed Circuit Board VFO unit assembly	50KΩB
	71500174       71500174       71500188       71500188       71500188       71500188       71500188       71500188       71500188       71500188       71500188       71500174       71500188       69010012       69010012       40143101       40143102       40143102       40143103       40143105	Image: CRYSTAL           71500174         HC-25/U         3.680           71500188         4         3.753           71500188         4         3.680           71500188         4         3.680           71500188         4         0ptid           4         4         0ptid           7         CRYSTAL         SOCKE           69010012         HC-25/U         1           69010012         HC-25/U         1           7         7         7         1           40143101         Carbon Film         1           40143102         4         7         1           40143102         4         7         1           40143102         4         7         1           40143103         4         7         1           40143104         4         7         1           40143105         3         7         1           40143104         4         7         1           40143105         3         7         1           40143105         3         7         1           40143105         3         7         1	21015550         Silicon Diode           Image: CRYSTAL         CRYSTAL           71500174         HC-25/U         3.8864MHz           71500178         *         11750Hz           71500188         *         3.1750Hz           71500174         HC-25/U         3.8864MHz           71500188         *         0ption           71500174         MC-25/U         SB4MHz           71500174         MC-25/U         SD0105           69010012         HC-25/U         SD0105           69010012         HC-25/U         SD0105           7         7         *           7         8         *         7           69010012         HC-25/U         SD0105           7         7         *         7           40143101         Carbon Film         ½W         1           40143102         *         *         7           40143103         *         *         7           40143104         *         *         7           40143105         *         *         7           40143104         *         *         7           40143105         *         *	21015550         Silicon Diode         1S1555           CRYSTAL	21015550       Silicon Diode       1S1555       J1101         CRYSTAL	21015550       Silicon Diode       1S1555       J1101       68060013         CRYSTAL       Image: CRYSTAL SOCKET       Image: CRYSTAL SOCKET       P1101       67040006         71500174       HC-25/U       1880 Hg. Tone) # 210060-2       Image: CRYSTAL SOCKET       Image: CRYSTAL SOCKET <t< td=""><td>21015550         Silicon Diode         1S1555         J1101         68060013         3022-06A           CRYSTAL         PLUG         PLUG</td></t<>	21015550         Silicon Diode         1S1555         J1101         68060013         3022-06A           CRYSTAL         PLUG         PLUG

	1	RESISTOR		-			1	DIODE				
R1302	40143101	Carbon Film	1⁄4 W	VJ	100Ω	D1401	21015550	Silicon	Diode		15	1555
R1310	40143151	<i>y y</i>	4 11	*	150Ω	D1401	210100043	Zener	%		China and C	Z090
R1307	40143471	" "	"	"	470Ω	51100	21030040	Zener				2030
R1308	40143222	" "	"	"	2.2KΩ							
R1305	40143272		"		2.7KΩ							
R1301	40143332	<i>4 4</i>	"	"	3.3KΩ		1	RESISTOR			-	
R1303	40143183	<i>4 4</i>	"	4	18KΩ	R1401	40143331	Carbon	Film	1⁄4W	VJ	330Ω
R1304	40143333	* *	"	"	33KΩ	R1406	40143471	"	"	*	"	470Ω
R1306,1309	40143104	<i>""</i>	"	"	100KΩ	R1402	40143561	"	"	"	"	560Ω
						R1403	40143821	"	"	*	"	820Ω
						R1404	40143272	"	"	"	"	2.7K
						R1405	44144059	Wire W	ound	"		0.050
		CAPACITOR					-					
C1302	31820040	Ceramic Disc	50WV		1.1.0.0.1.							
C1304	31820330	* *		33PF								
C1313	31820390	"		39PF	_16.265			POTENTION	IETER			
C1305	31820510	4 4		51PF	20,005,125	VR1401	49905471	SR19R				470Ω
C1311	31820680	* *		68PF								-
C1307,1310	31820221	" "		220PF	214222							
C1306	31820271	" "		270PF	(22.5 km)							
C1301	31827040	* *		4PF	12000			CAPACITOR	5			
C1303	31827070	" "		7PF		C1402	30820102	Ceramic		50W V		001µF
C1308,1309,1312,	30820103	" "	"	0.01µ	F	C1404	34220476	Electro	ytic	16WV		
C1314~1316						C1403	34220227	"		"		μF
						C1401	35320108	*		25WV	100	00μF
VC1301	39000027	C521-112A	TUR				91100008	Wrappin	a torm	inal C		
101001	0000021	0021 1124					91100008	Wrappir				
		TRIMMER CAPAC	ITOR									
TC1301	39000070	TSN-100D15			15PF							
TC1302	39000005	ECV-1ZW	50×32		50PF		LEVER	SWITCH	board			
						Symbol Number	Parts Number		Descri	iption		
1						ey moor, i tamber	Number					
						PB-1777	60417770	Printed				
		INDUCTOR						Printed PCB wi	Circuit	t Board		
	55003276	INDUCTOR		# 22	20314		60417770		Circuit	t Board		
L1303	55003276 53010001	Micro Inductor			20314 10µ H		60417770		Circuit	t Board		
L1303		1					60417770		Circuit	t Board		
L1303	53010001	Micro Inductor			10µ H	PB-1777	60417770		Circuit	t Board		
L1303	53010001	Micro Inductor			10µ H		60417770	PCB wi	Circuit th comp	t Board	TJ	15ΚΩ
L1303 L1302	53010001	Micro Inductor			10µ H	PB-1777	60417770 017770AZ	PCB wi	Circuit th comp	t Board ponents	TJ ″	
L1303 L1302	53010001 53030001	Micro Inductor			10µ H	PB-1777 R1502	60417770 017770AZ 41143153	PCB wi RESISTOR Carbon	Circuit th comp Film	t Board ponents	"	22KΩ
L1303 L1302	53010001 53030001	Micro Inductor // // CONNECTOR SI-6303 Wrapping termi	inal C		10µ H	PB-1777 R1502 R1501	60417770 017770AZ 41143153 41143223	PCB wi RESISTOR Carbon	Circuit th comp Film	t Board ponents	"	22KΩ
L1303 L1302	53010001 53030001	Micro Inductor	inal C		10µ H	PB-1777 R1502 R1501	60417770 017770AZ 41143153 41143223	PCB wi RESISTOR Carbon	Circuit th comp Film	t Board ponents	"	22ΚΩ
L1303 L1302 J1301	53010001 53030001 53030001 91100008 91100008 91001102 RE	Micro Inductor	inal C A102		10µ H	PB-1777 R1502 R1501	60417770 017770AZ 41143153 41143223	PCB wi RESISTOR Carbon	Circuit th comp Film	t Board ponents	"	22ΚΩ
L1303 L1302 J1301 Symbol Number	53010001 53030001 	Micro Inductor	inal C A102		10µ H	PB-1777 R1502 R1501	60417770 017770AZ 41143153 41143223	PCB wi RESISTOR Carbon	Circuit th comp Film	t Board ponents	"	22ΚΩ
L1303 L1302 J1301 Symbol Number	53010001 53030001 91100008 91100008 91001102 Re Rerts Number 60417561	Micro Inductor # # CONNECTOR SI-6303 Wrapping termi Seal terminal EG board Descri Printed Circuit	inal C A102		10µ H	PB-1777 R1502 R1501	60417770 017770AZ 41143153 41143223	PCB wi	Circuit th comp Film	t Board ponents ¼W * tion ½W	"	22KΩ
L1303 L1302 J1301 Symbol Number	53010001 53030001 91100008 91001102 Parts Number	Micro Inductor # # CONNECTOR SI-6303 Wrapping termi Seal terminal EG board Descri Printed Circuit	inal C A 102 iption t Board		10µ H	PB-1777 R1502 R1501 R1503,1504	60417770 017770AZ 41143153 41143223 42124331	PCB wi	Circuit th comp Film Ø omposit	t Board ponents ¼W % tion ½W	"	22KΩ
L1303 L1302 J1301 Symbol Number	53010001 53030001 91100008 91100008 91001102 Re Rerts Number 60417561	Micro Inductor	inal C A102 iption t Board ponents		10µ H	PB-1777 R1502 R1501 R1503,1504 S1501,1505	60417770 017770AZ 41143153 4114323 42124331 	PCB wi	Circuit th comp Film omposit	t Board ponents ¼W % tion ½W	"	22KΩ
L1303 L1302 J1301 Symbol Number PB-1756A	53010001 53030001 91100008 91100008 91001102 Parts Number 60417561 017561AZ	Micro Inductor # # CONNECTOR SI-6303 Wrapping terminal Seal terminal EG board Descrit Printed Circuit PCB with comp IC & TRANSISTOR	inal C A102 iption t Board ponents		10µ H 1mH	PB-1777 R1502 R1501 R1503,1504 S1501,1505	60417770 017770AZ 41143153 4114323 42124331 	PCB wi	Circuit th comp Film omposit	t Board ponents ¼W % tion ½W	"	22ΚΩ
L 1301 L 1303 L 1302 J 1301 Symbol Number PB-1756A Q1404 Q1401	53010001 53030001 91100008 91100008 91001102 Re Rerts Number 60417561	Micro Inductor	inal C A102 iption t Board ponents R		10µ H 1mH	PB-1777 R1502 R1501 R1503,1504 S1501,1505	60417770 017770AZ 41143153 4114323 42124331 	PCB wi	Circuit th comp Film omposit	t Board ponents ¼W % tion ½W	"	15KΩ 22KΩ 330Ω

	PUSH	SWITCH board	R1707,1714	40143103	Carbon	Film 3	W4W	VJ	10KΩ
Symbol Number	Parts Number	Description	R1706,1709	40143223	"	*	"	"	22KΩ
PB-1832A	60418321	Printed Circuit Board							
	018321AZ	PCB with components							
									-
		DIODE			CAPACITOR	1		-	
D1601~1603,1605	21090140	LED GD4 203SRD	C1709~1712	31820470	Ceramic	Disc 5	50W V	471	PF CH
D1604	21090011	Silicon Diode 10D1	C1720,1726	31829059	"	"	"	0.5P	FSL
			C1728	31829050	"	"	4	5PF	SL
			C1725	31829070	"	"	"	7PF	SL
			C1727	31829090	"	"	"	9PF	SL
		RESISTOR	C1716	31829220	"	4	"	22PF	SL
R1604	42124221	Carbon Composition ½WGK 220Ω	C1719	31829270	"	"	"	27PF	SL
R1601~1603	42124331	» » » » 330Ω	C1721,1722	31829300	"	"	"	30PF	SL
			C1723,1724	30820102	"	"	"	0.001	μF
			C1705~1708,1713,	30820103	"	"	"	0.014	μF
			C1717,1718						
			C1729~1733	32821102	Feed Th	ru	"	10001	PF
			C1715	36824101	Styrol		*	100P	F
		POTENTIOMETER	C1714	36824221	"		"	220P	F
VR1601	49906104	EVL-SOAA 00B15 100KΩB	C1701~1704	34220106	Electrol	ytic 1	16W V	10µ F	
		SWITCH							
S1601~1604	65000036	MB-0202AA2060 B-2U-EE							
S1605	65000037	MB-0201AA2060 B-2U-OA			TRIMMER		OR		
51005	0300037	MD 0201112000 B-20-0A	TC1701~1704	39000070		W 30×4	Sector De la		30PI
					INDUCTOR				
		INTER LOCAL) unit	L1701~1705	53020001	Micro	Inductor		FL5H	H 1mH
Symbol Number	Parts Number	Description					_		
PB-1761	60417610	Printed Circuit Board							
PB-1804	60418040	Connector Board							
	017610AZ	OSC unit with components			TRANSFOR				
			T1701,1702	54147970	R-12	4797			220110
			T1703,1704	54141020	R-12	4102		#2	220111
		TRANSISTOR							
Q1701	22303730	Silicon Transistor 2SC373	TTD1 804 . 1808						
Q1702,1703	22307104	* * 2SC710	TP1701~1707	91100008	Wrappir	ng termina	al C		
					MINI CONN	ECTOR			
			J1701	67130001	5048-13	A			
		DIODE	Print Scine 10						
D1701~1704	21090142	Silicon Diode MC301							
				COU	NTER uni	t			
			Symbol Number	Parts Number		Descript	tion		
			PB-1734	60417340	LED bo		- 0		
		CRYSTAL	PB-1735	60417350	Counter				
X1701	71800099	HC-18/U 14.3667MHz #210054	PB-1803	60418030	Connect	or board			
				017350AZ		unit Ass	embly		
		RESISTOR	a state of the second se					_	
R1712,1713,1717	40143101	RESISTORCarbon Film½WVJ100Ω			IC FET &	TRANSIS	STOR		
R1712,1713,1717 R1716	40143101 40143221		Q1802	25000104	IC FET &	TRANSIS	STOR	SN	76514
R1716		Carbon Film ¼W VJ 100Ω	Q1802 Q1805	25000104 25000054		TRANSIS	STOR		
R1716 R1711	40143221	Carbon Film         ¼W         VJ         100Ω           #         #         #         #         220Ω	Q1805 Q1806	15-8.901996-639	IC	TRANSIS	STOR	MS	
	40143221 40143561	Carbon Film         ¼W         VJ         100Ω           *         *         *         220Ω           *         *         *         *         560Ω	Q1805 Q1806	25000054	IC *	TRANSIS	STOR	MS F4	SM5564

Q1818	25000085	IC		MC	M561	C1843	24100477	El	101011	170. 17
Q1819~1821	25000085	// // // // // // // // // // // // //		1922012-03	an an each ann an	C1843	34120477	Electrolytic	16W V	470µ F
Q1801	25000154	FET			75453 (19GR					
Charles and the second s		17439-4074					-			
Q1803 Q1804,1809	22307842	Transistor			C784R		-			
	22303724			12000	C372Y					
Q1810	22104963	"		1.000	\496					
Q1811~1817	22304960	"			2496			TRIMMER CAPAC		
Q1822~1828	21090135	7 Segment Ll	ED	508	2-7740	TC1801	39000011	ECV-1ZW	20×53	20PF
							100			
		IC SOCKET						INDUCTOR		2
DS1801	68140008	116-14-30-114		14P		L1801,1802	53020014	INDUCTOR Micro Inductor	FI	.4H 1.8µH
DS1802	68280001	116-28-30-114		28P		1001,1002	00020014	Micro inductor		.411 1.0411
051802	00200001	110 20 00 111		201	-		-	MINI CONNECTOR	>	
							67100007	5048-10A		
							01100001	TRANSFORMER		
		DIODE				T1801,1802	55003261	THATSI ON THE		# 220312
D1801	21090011	Silicon Diode		100	01	T1801,1002	55003174			# 220312
01001	21030011	STITEON DIOLE		101	~ <b>1</b>	11003	55005174			# 220209
							91001102	Seal terminal	A-102	
		. A						and torminal		
		CRYSTAL				TP1801~1806	91100008	Wrapping term	inal C	
X1801	71600033	HC-6/W 1.31	072MHz	#2	10056					
							67200003	Board joint 16	3740	
		RESISTOR						D board	and the second	-
R1833,1835	40143470	Carbon Film	1/4 W	VJ	47Ω	Symbol Number			in tinn	
R1845	40143470		74 W	VJ	4712 56Ω		Parts Number	Descr		
R1824,1834	40143560	* *	"	"		PB-1801	60418010	Printed Ciruit		
	40143820		A		82Ω 1000		018010AZ	PCB with com	oonents	
R1805,1806,1836~1842			"	"	100Ω					
R1809 R1813,1823	40143221		*	"	220Ω		_			
	40143471	" "	"	"	470Ω					
R1803,1810	40143102	* *	*	"	1KΩ	D1001 1005	01000110	DIODE	ANAGADA	
R1807	40143392	" "	"	"	3.9KΩ	D1901~1907	21090140	LED GD-4	203SRD	
R1815,1817,1818,	40143103	" "	"	"	10KΩ		_			
R1820~1822,1843					1-110					
R1808,1811,1812	40143153	" "	"	"	15KΩ		_			
R1816,1819	40143563	" "	"	"	56KΩ	D		RESISTOR		
R1802,1814	40143104	* *	"	"	100KΩ	R1901~1905	42124331	Carbon Compos	ition $\frac{1}{2}$	W 330Ω
R1844	40143224	" "	"	"	220KΩ					
R1832	40143564	" "	*	"	560KΩ		_			
R1825~1831	42124330		tion ½W	GK	33Ω					
							OLICE			
						Symbol Number		R AMP board	intica	
						PB-1671A ·	Parts Number	Printed Circui		
		CAPACITOR				ID INTA	60416711 016711AZ		1991 ES 11.57 & LC	
C1824,1825	31820510	Ceramic Disc	50W	51PF	CH		OTOTIAL	1 CB with com	onents	
C1824, 1825	31829059			0.5PF	15 A 16					
C1801,1805,1807,1808				5PF	11293104					
C1801, 1805, 1807, 1808	31829050			27PF				FET		
C1827~1831	31829221	* *		27PF 220PF		Q2001	22200105	FET		SK10CD
C1802, 1804, 1809, 1810				0.001		42001	22800195	FEI		2SK19GR
C1802, 1804, 1809, 1810 C1812~1816, 1819,	30820102		"	0.001	H I					
C1812~1816,1819, C1844~1848										
C1844~1848	30820103	" "		0.01µ	F			RESISTOR	-	
C1823, 1826, 1832, 1836			<i>x</i>	0.01µ	r .	D9009 9009	41149101		1/11/11	1000
C1823, 1826, 1832, 1836						R2002,2003	41143101	Carbon Film	1/4W TJ	
	26016227	Tontalum	6 211/1	, ,	20. F	R2004	41143102	a sea an	* *	1KΩ
C1734	36916337	Tantalum *	6.3WV		30µF	R2001	41143104	" "	" "	100ΚΩ
C1839~1842	32821102	Feed Thru	50WV		.001µF					
C1833,1838 C1803	34220106 34120107	Electrolytic	16WV 10WV		10μ F 100μ F					
		"								

		CARACITOR				
C2004	31829060	CAPACITOR Ceramic Disc 50WV 6PF S	. TC2101	20000007	TRIMMER CAPACITOR	
C2004	31829060			39000007	ECV 1ZW 20×40	
C2001						
02002,2003	30820102	* * * 0.001µF				
				-	INDUCTOR	
			L2101	53010002	Micro Inductor	22µ H
			L.2102	53010002	1 // //	250µ H
			1.2102	00010000		20041
		TRANSFORMER				
T2001	54141020	R12-4102 # 2201	11			
				91100008	Wrapping terminal C	
		KER unit				
Symbol Number	Parts Number	Description				
		Printed Circuit Board			AY board	
PB-1802	60418020	Marker board	Symbol Number	Parts Number	Description	
PB-1804	60418040	Connector board	PB-1829	60418290		
	018020AZ	Marker unit with components		018290AZ	PCB with components	
	-					
Q2103	25000108	IC & TRANSISTOR				
		IC 34024PC Transistor 2SC372Y	DI 0201	70000021	RELAY	
Q2101,2102,2104	22303724	Transistor 25C3721	RL2301	70000031	BR-211 D012M	
		DIODE		ACC	ESSORIES	
D2101	21090139	Zener RD8.2EB	Symbol Number	Parts Number	Description	
				77000011	Microphone Assembly YE-	-11
	1		· · · · · · · · · · · · · · · · · · ·		with Microphone hanger	
				67040001	Microphone Plug FM-1	44P
		CRYSTAL		67020005	Antenna plug	PL-259
X2101	71800060	HC-18/U 12.8MHz		67050003	Accessory plug	CP-0084
				67020002	Key plug	SH-3001
				67020003	External Speaker plug	P-2240
				67020003	Headphone plug	P-2240
		RESISTOR			Plug adaptor	KA-409
R2109	40143271	Carbon Film <sup>1</sup> / <sub>4</sub> W VJ 27	Ω	67020001	RCA plug	CN-7017P
R2103,2105	40143102	* * * * 11	Ω	73000003	Fuse 3A (AC)	
R2108	40143222		2ΚΩ	73000005	Fuse 10A (DC)	
R2102	40143103		KΩ	96000001	AC power cord	# 240011
R2101,2107	40143223		KΩ	68040005		QMSP4FK
R2106	40143104		ΟΚΩ	96000003		# 240068
R2104	40143224	* * * * 22	ΟΚΩ	68040005		QMSP4FK
				6900002		SN1102
				67020008	Cigarette lighter adaptor	
		CAPACITOR				-
C2101,2107	31820270	Ceramic Disc 50WV 27P C				
02101,2101	01020210	* * * 220PFC		-		
C2102.2103	31820221					
C2102,2103 C2108	31820221 31829030					
C2108	31829030	* * * 3PF S		_		
C2108 C2104~2106,2110	31829030 30820103	* * * 3PF S * * * 0.01µF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				
C2108 C2104~2106,2110	31829030 30820103	* * * 3PF S * * * 0.01µF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				
C2108 C2104~2106,2110 C2111	31829030 30820103 32821102	*         *         3PF S           *         *         0.01 µ F           Feed Tnru         50W 1000 PF				